

# Boost/SEPIC/Inverting DC/DC Converter with 65V Switch, Soft-Start and Synchronization

## FEATURES

- 65V Power Switch
- Current Limit Options of 0.5A (LT8570) or 0.25A (LT8570-1)
- Adjustable Switching Frequency
- Single Feedback Resistor Sets  $V_{OUT}$
- Synchronizable to External Clock
- High Gain  $\overline{SHDN}$  Pin Accepts Slowly Varying Input Signals
- Wide Input Voltage Range: 2.55V to 40V
- Low  $V_{CESAT}$  Switch
- Integrated Soft-Start Function
- Easily Configurable as a Boost, SEPIC, or Inverting Converter
- User Configurable Undervoltage Lockout (UVLO)
- Pin Compatible with LT3580 and LT8580
- Tiny Thermally Enhanced 8-Lead 3mm × 3mm DFN and 8-Lead MSOP Packages

## APPLICATIONS

- VFD Bias Supplies
- TFT-LCD Bias Supplies
- GPS Receivers
- DSL Modems
- Local Power Supply

## DESCRIPTION

The **LT<sup>®</sup>8570** and **LT8570-1** are PWM DC/DC converters. The LT8570 contains a 0.5A, 65V power switch, while the LT8570-1 contains a 0.25A, 65V power switch. The LT8570 and LT8570-1 can be configured as either a boost, SEPIC or inverting converter.

The LT8570/LT8570-1 have an adjustable oscillator, set by a resistor from the RT pin to ground. Additionally, the LT8570/LT8570-1 can be synchronized to an external clock. The switching frequency of the part may be free running or synchronized, and can be set between 200kHz and 1.5MHz.

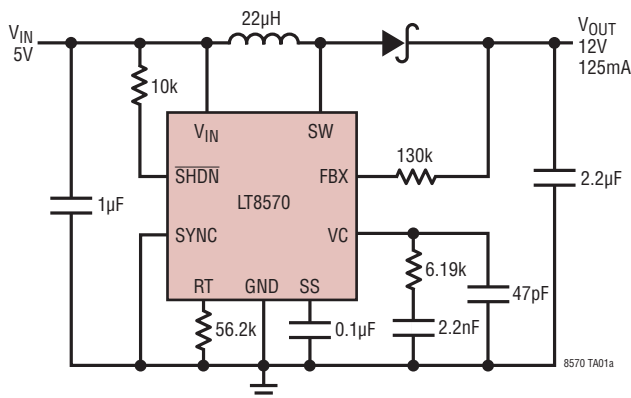
The LT8570/LT8570-1 also feature innovative  $\overline{SHDN}$  pin circuitry that allows for slowly varying input signals and an adjustable undervoltage lockout function.

Additional features such as frequency foldback and soft-start are integrated. The LT8570/LT8570-1 are available in tiny thermally enhanced 3mm × 3mm 8-lead DFN and 8-lead MSOP packages.

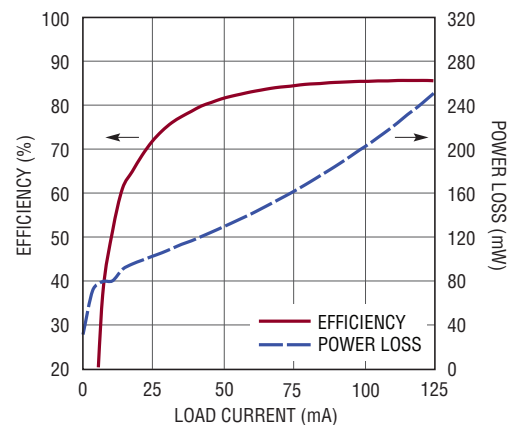
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## TYPICAL APPLICATION

1.5MHz, 5V to 12V Boost Converter



Efficiency and Power Loss



8570 TA01b

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# LT8570/LT8570-1

## ABSOLUTE MAXIMUM RATINGS (Note 1)

$V_{IN}$ Voltage.....	–0.3V to 40V	SYNC Voltage.....	–0.3V to 5.5V
SW Voltage .....	–0.4V to 65V	Operating Junction Temperature Range	
RT Voltage .....	–0.3V to 5V	LT8570E, LT8570-1E (Notes 2, 5) .....	–40°C to 125°C
SS Voltage .....	–0.3V to 2.5V	LT8570I, LT8570-1I (Notes 2, 5) .....	–40°C to 125°C
FBX Voltage.....	5V	LT8570H, LT8570-1H (Notes 2, 5) .....	–40°C to 150°C
FBX Current.....	–1mA	Storage Temperature Range .....	–65°C to 150°C
VC Voltage .....	–0.3V to 2V	Lead Temperature (Soldering, 10 sec)	
SHDN Voltage .....	–0.3V to 40V	MS8E Package Only.....	300°C

## PIN CONFIGURATION

<p>TOP VIEW</p> <p>DD PACKAGE 8-LEAD (3mm × 3mm) PLASTIC DFN <math>\theta_{JA} = 43^{\circ}\text{C/W}</math> EXPOSED PAD (PIN 9) IS GND, MUST BE SOLDERED TO PCB</p>	<p>TOP VIEW</p> <p>MS8E PACKAGE 8-LEAD PLASTIC MSOP <math>\theta_{JA} = 35^{\circ}\text{C/W TO } 40^{\circ}\text{C/W}</math> EXPOSED PAD (PIN 9) IS GND, MUST BE SOLDERED TO PCB</p>
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## ORDER INFORMATION <http://www.linear.com/product/LT8570#orderinfo>

LEAD FREE FINISH	TAPE AND REEL	PART MARKING*	PACKAGE DESCRIPTION	TEMPERATURE RANGE
LT8570EDD#PBF	LT8570EDD#TRPBF	LGRY	8-Lead (3mm × 3mm) Plastic DFN	–40°C to 125°C
LT8570IDD#PBF	LT8570IDD#TRPBF	LGRY	8-Lead (3mm × 3mm) Plastic DFN	–40°C to 125°C
LT8570HDD#PBF	LT8570HDD#TRPBF	LGRY	8-Lead (3mm × 3mm) Plastic DFN	–40°C to 150°C
LT8570EMS8E#PBF	LT8570EMS8E#TRPBF	LTGRZ	8-Lead Plastic MSOP	–40°C to 125°C
LT8570IMS8E#PBF	LT8570IMS8E#TRPBF	LTGRZ	8-Lead Plastic MSOP	–40°C to 125°C
LT8570HMS8E#PBF	LT8570HMS8E#TRPBF	LTGRZ	8-Lead Plastic MSOP	–40°C to 150°C
LT8570EDD-1#PBF	LT8570EDD-1#TRPBF	LGSB	8-Lead (3mm × 3mm) Plastic DFN	–40°C to 125°C
LT8570IDD-1#PBF	LT8570IDD-1#TRPBF	LGSB	8-Lead (3mm × 3mm) Plastic DFN	–40°C to 125°C
LT8570HDD-1#PBF	LT8570HDD-1#TRPBF	LGSB	8-Lead (3mm × 3mm) Plastic DFN	–40°C to 150°C
LT8570EMS8E-1#PBF	LT8570EMS8E-1#TRPBF	LTGSC	8-Lead Plastic MSOP	–40°C to 125°C
LT8570IMS8E-1#PBF	LT8570IMS8E-1#TRPBF	LTGSC	8-Lead Plastic MSOP	–40°C to 125°C
LT8570HMS8E-1#PBF	LT8570HMS8E-1#TRPBF	LTGSC	8-Lead Plastic MSOP	–40°C to 150°C

Consult LTC Marketing for parts specified with wider operating temperature ranges. \*The temperature grade is identified by a label on the shipping container.

For more information on lead free part marking, go to: <http://www.linear.com/leadfree/>

For more information on tape and reel specifications, go to: <http://www.linear.com/tapeandreel/>. Some packages are available in 500 unit reels through designated sales channels with #TRMPBF suffix.

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# ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at  $T_A = 25^\circ\text{C}$ .  $V_{IN} = 5\text{V}$ ,  $V_{SHDN} = V_{IN}$  unless otherwise noted. (Note 2)

PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
Operating Voltage Range	$-40^\circ\text{C}$ to $125^\circ\text{C}$	●	2.55		40	V
	$-40^\circ\text{C}$ to $150^\circ\text{C}$	●	2.9		40	V
Positive Feedback Voltage		●	1.185	1.204	1.220	V
Negative Feedback Voltage		●	-3	3	12	mV
Positive FBX Pin Bias Current	$V_{FBX}$ = Positive Feedback Voltage, Current Into Pin	●	81	83.3	85	$\mu\text{A}$
Negative FBX Pin Bias Current	$V_{FBX}$ = Negative Feedback Voltage, Current Out of Pin	●	81	83.3	86	$\mu\text{A}$
Error Amplifier Transconductance				200		$\mu\text{mhos}$
Error Amplifier Voltage Gain				60		V/V
Quiescent Current	$V_{SHDN} = 2.5\text{V}$ , Not Switching			1.2	1.7	mA
Quiescent Current in Shutdown	$V_{SHDN} = 0\text{V}$			0	1	$\mu\text{A}$
Reference Line Regulation	$2.55\text{V} \leq V_{IN} \leq 40\text{V}$			0.01	0.05	%/V
Switching Frequency, $f_{OSC}$	$R_T = 56.2\text{k}$	●	1.23	1.5	1.77	MHz
	$R_T = 422\text{k}$	●	165	200	235	kHz
Switching Frequency in Foldback	Compared to Normal $f_{OSC}$			1/6		Ratio
Switching Frequency Set Range	SYNCing or Free Running	●	200		1500	kHz
SYNC High Level for Synchronization		●	1.3			V
SYNC Low Level for Synchronization		●			0.4	V
SYNC Clock Pulse Duty Cycle	$V_{SYNC} = 0\text{V}$ to $2\text{V}$		35		65	%
Recommended Minimum SYNC Ratio $f_{SYNC}/f_{OSC}$				3/4		
Minimum Off-Time				100		ns
Minimum On-Time				100		ns
Switch Current Limit	Minimum Duty Cycle (Note 3), LT8570	●	0.6	0.75	1	A
	Maximum Duty Cycle (Notes 3, 4), LT8570, $f_{OSC} = 1.5\text{MHz}$	●	0.27	0.5	0.85	A
	Maximum Duty Cycle (Notes 3, 4), LT8570, $f_{OSC} = 200\text{kHz}$	●	0.15	0.4	0.8	A
	Minimum Duty Cycle (Note 3), LT8570-1	●	0.3	0.375	0.5	A
	Maximum Duty Cycle (Notes 3, 4), LT8570-1, $f_{OSC} = 1.5\text{MHz}$	●	0.15	0.25	0.43	A
	Maximum Duty Cycle (Notes 3, 4), LT8570-1, $f_{OSC} = 200\text{kHz}$	●	0.075	0.2	0.4	A
Switch $V_{CESAT}$	$I_{SW} = 0.4\text{A}$ (LT8570)			250		mV
	$I_{SW} = 0.2\text{A}$ (LT8570-1)			250		mV
Switch Leakage Current	$V_{SW} = 5\text{V}$			0.01	1	$\mu\text{A}$
Soft-Start Charging Current	$V_{SS} = 0.5\text{V}$	●	4	6	8	$\mu\text{A}$
$\overline{\text{SHDN}}$ Minimum Input Voltage High	Active Mode, $\overline{\text{SHDN}}$ Rising	●	1.23	1.31	1.4	V
	Active Mode, $\overline{\text{SHDN}}$ Falling	●	1.21	1.27	1.33	V
$\overline{\text{SHDN}}$ Minimum Input Voltage Hysteresis				40		mV
$\overline{\text{SHDN}}$ Input Voltage Low	Shutdown Mode	●			0.3	V
$\overline{\text{SHDN}}$ Pin Bias Current	$V_{SHDN} = 3\text{V}$			44	56	$\mu\text{A}$
	$V_{SHDN} = 1.3\text{V}$		9	12	15	$\mu\text{A}$
	$V_{SHDN} = 0\text{V}$			0	0.1	$\mu\text{A}$

**Note 1:** Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

**Note 2:** The LT8570E/LT8570-1E are guaranteed to meet performance specifications from  $0^\circ\text{C}$  to  $125^\circ\text{C}$  junction temperature. Specifications over the  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  operating junction temperature range are assured by design, characterization and correlation with statistical process controls. The LT8570I/LT8570-1I are guaranteed over the full  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  operating junction temperature range. The LT8570H/LT8570-1H are guaranteed over

the full  $-40^\circ\text{C}$  to  $150^\circ\text{C}$  operating junction temperature range. Operating lifetime is derated at junction temperatures greater than  $125^\circ\text{C}$ .

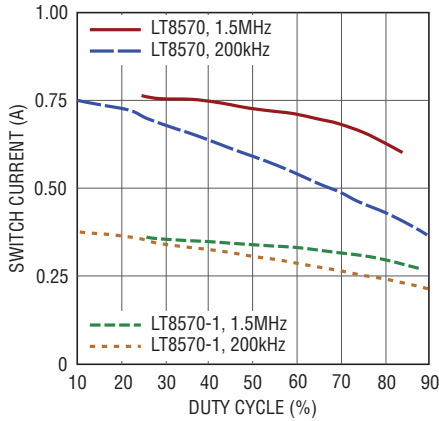
**Note 3:** Current limit guaranteed by design and/or correlation to static test.

**Note 4:** Current limit measured at equivalent of listed switching frequency.

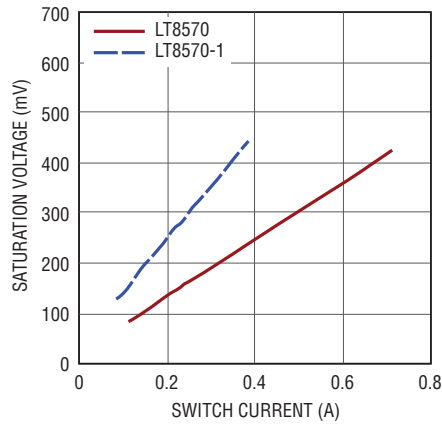
**Note 5:** This IC includes overtemperature protection that is intended to protect the device during momentary overload conditions. Junction temperature will exceed  $150^\circ\text{C}$  when overtemperature protection is active. Continuous operation above the specified maximum operating junction temperature may impair device reliability.

## TYPICAL PERFORMANCE CHARACTERISTICS $T_A = 25^\circ\text{C}$ , unless otherwise specified

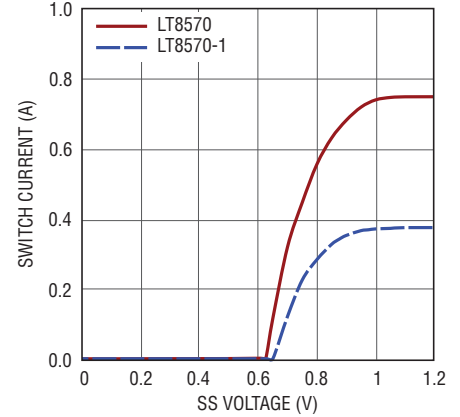
Switch Current Limit vs Duty Cycle



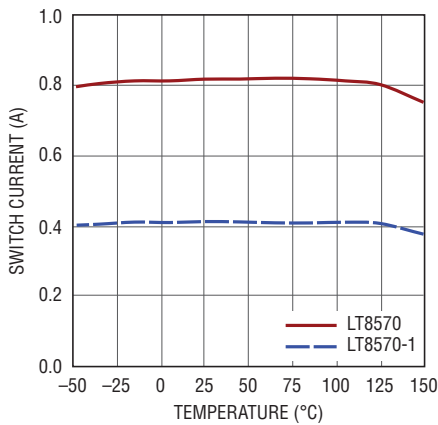
Switch Saturation Voltage



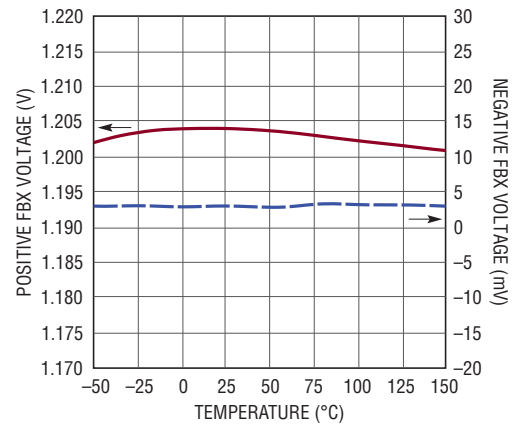
Maximum Switch Current vs SS



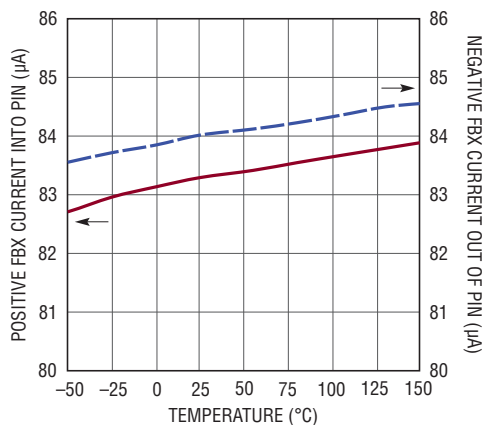
Switch Current Limit vs Temperature



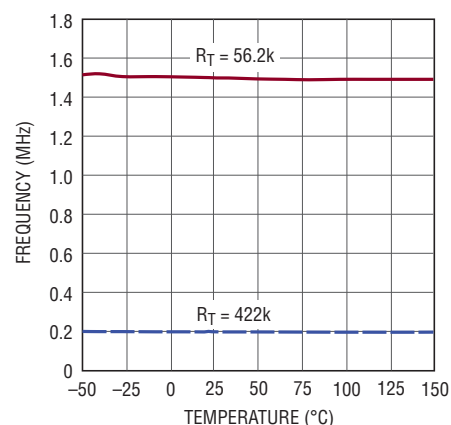
Positive and Negative Output Voltage Regulation



Positive and Negative FBX Current at Output Voltage Regulation

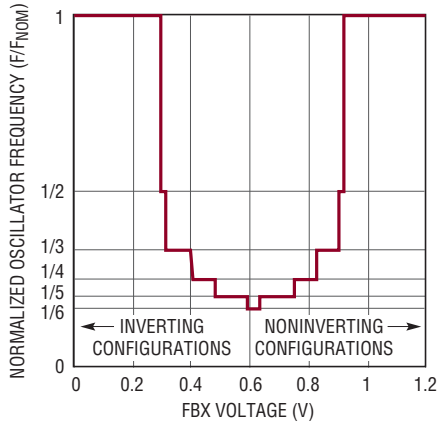


Oscillator Frequency



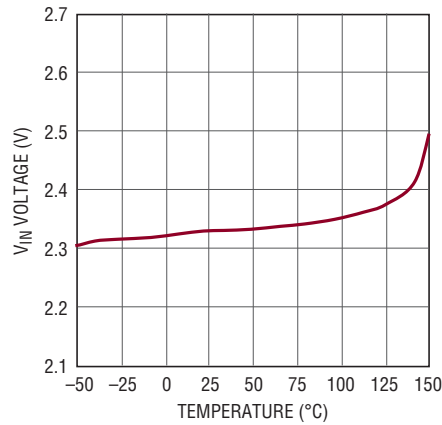
# TYPICAL PERFORMANCE CHARACTERISTICS $T_A = 25^\circ\text{C}$ , unless otherwise specified

## Oscillator Frequency During Soft-Start



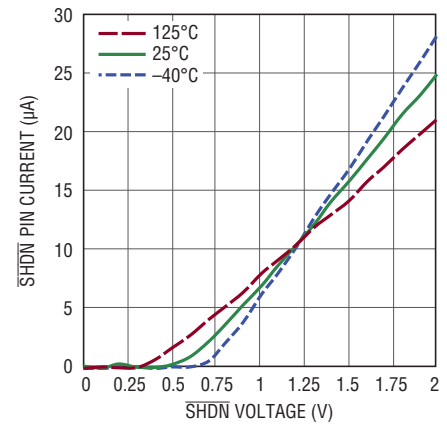
8570 G08

## Internal UVLO



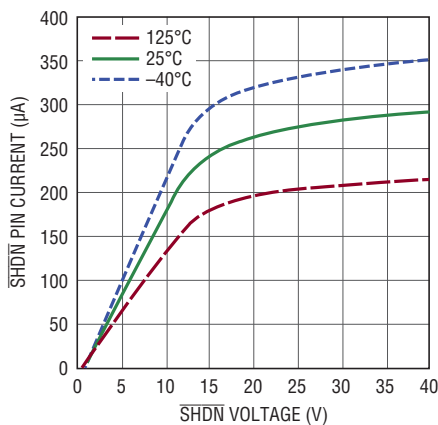
8570 G09

## SHDN Pin Current



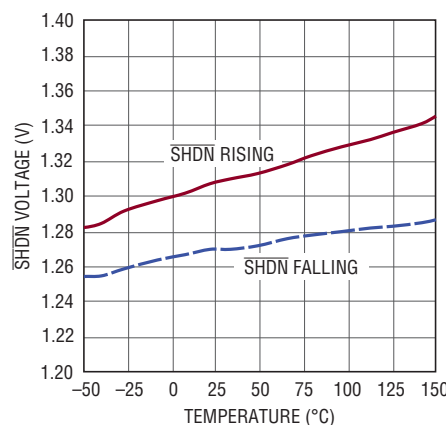
8570 G10

## SHDN Pin Current



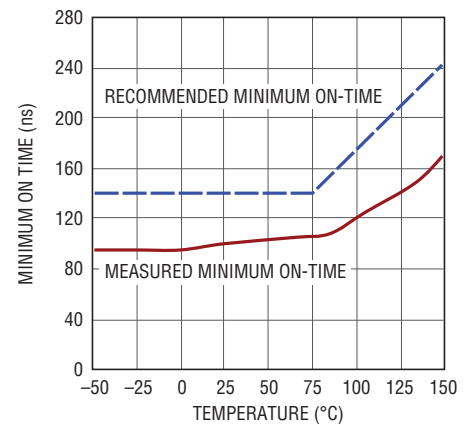
8570 G11

## Active/Lockout Threshold



8570 G12

## Minimum On-Time vs Temperature



8570 G13

## PIN FUNCTIONS

**FBX (Pin 1):** Positive and Negative Feedback Pin. For a noninverting or inverting converter, tie a resistor from the FBX pin to  $V_{OUT}$  according to the following equations:

$$R_{FBX} = \frac{(V_{OUT} - 1.204V)}{83.3\mu A}; \text{ Noninverting Converter}$$

$$R_{FBX} = \frac{(|V_{OUT}| + 3mV)}{83.3\mu A}; \text{ Inverting Converter}$$

**VC (Pin 2):** Error Amplifier Output Pin. Tie external compensation network to this pin.

**$V_{IN}$  (Pin 3):** Input Supply Pin. Must be locally bypassed.

**SW (Pin 4):** Switch Pin. This is the collector of the internal NPN Power switch. Minimize the metal trace area connected to this pin to minimize EMI.

**$\overline{SHDN}$  (Pin 5):** Shutdown Pin. In conjunction with the UVLO (undervoltage lockout) circuit, this pin is used to enable/disable the chip and restart the soft-start sequence. Drive below 1.21V to disable the chip. Drive above 1.40V to activate the chip and restart the soft-start sequence. Do not float this pin.

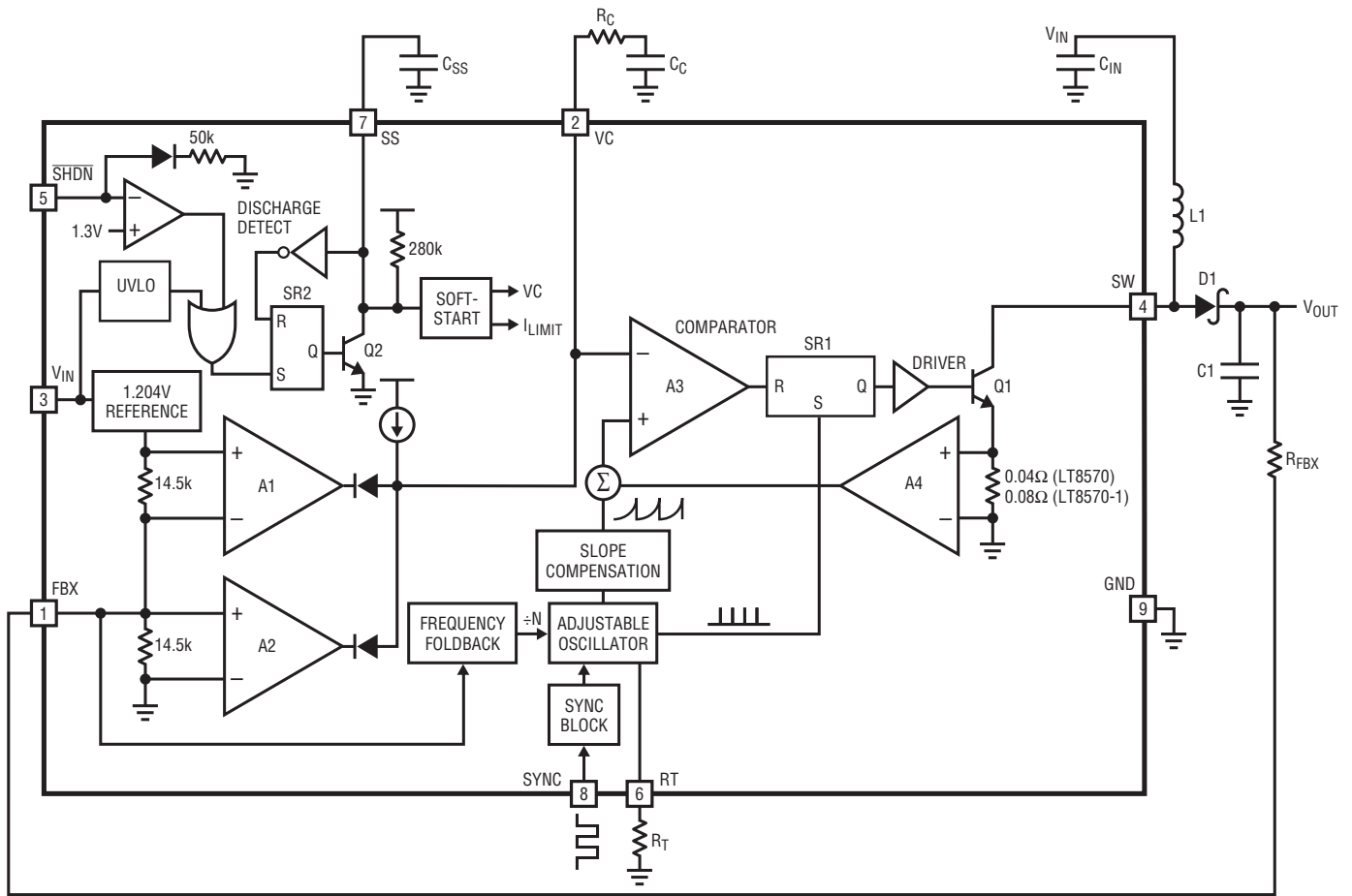
**RT (Pin 6):** Timing Resistor Pin. Adjusts the switching frequency. Place a resistor from this pin to ground to set the frequency to a fixed free running level. Do not float this pin.

**SS (Pin 7):** Soft-Start Pin. Place a soft-start capacitor here. Upon start-up, the SS pin will be charged by a (nominally) 280k resistor to about 2.1V.

**SYNC (Pin 8):** To synchronize the switching frequency to an outside clock, simply drive this pin with a clock. The high voltage level of the clock needs to exceed 1.3V, and the low level should be less 0.4V. Drive this pin to less than 0.4V to revert to the internal free-running clock. See the Applications Information section for more information.

**GND (Exposed Pad Pin 9):** Ground. Exposed pad must be soldered directly to local ground plane.

# BLOCK DIAGRAM



8570 BD

## OPERATION

The LT8570/LT8570-1 use a constant-frequency, current mode control scheme to provide excellent line and load regulation. Refer to the Block Diagram for the following description of the part's operation. At the start of each oscillator cycle, the SR latch (SR1) is set, which turns on the power switch, Q1. The switch current flows through the internal current sense resistor, generating a voltage proportional to the switch current. This voltage (amplified by A4) is added to a stabilizing ramp and the resulting sum is fed into the positive terminal of the PWM comparator A3. When this voltage exceeds the level at the negative input of A3, the SR latch is reset, turning off the power switch. The level at the negative input of A3 (VC pin) is set by the error amplifier A1 (or A2) and is simply an amplified version of the difference between the feedback voltage (FBX pin) and the reference voltage (1.204V or 3mV, depending on the configuration). In this manner, the error amplifier sets the correct peak current level to keep the output in regulation.

The LT8570/LT8570-1 have an FBX pin architecture that can be used for either noninverting or inverting configurations. When configured as a noninverting converter, the FBX pin is pulled up to the internal bias voltage of 1.204V by the  $R_{FBX}$  resistor connected from  $V_{OUT}$  to FBX. Amplifier A2 becomes inactive and amplifier A1 performs the inverting amplification from FBX to VC. When the LT8570/LT8570-1 are in an inverting configuration, the FBX pin is pulled

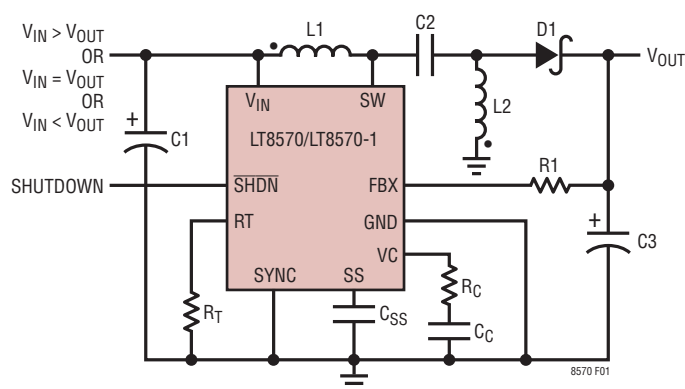
down to 3mV by the  $R_{FBX}$  resistor connected from  $V_{OUT}$  to FBX. Amplifier A1 becomes inactive and amplifier A2 performs the noninverting amplification from FBX to VC.

## SEPIC Topology

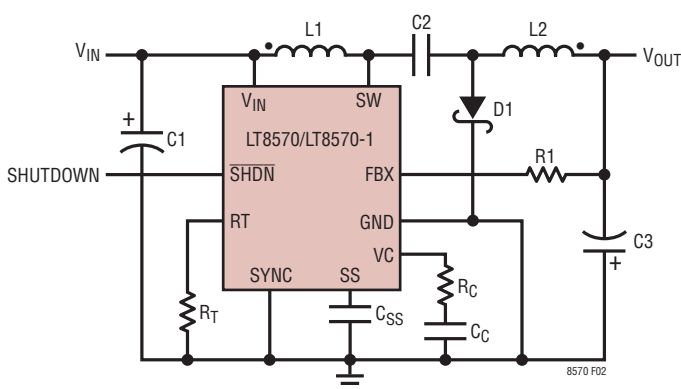
As shown in Figure 1, the LT8570/LT8570-1 can be configured as a SEPIC (single-ended primary inductance converter). This topology allows for the input to be higher, equal, or lower than the desired output voltage. Output disconnect is inherently built into the SEPIC topology, meaning no DC path exists between the input and output. This is useful for applications requiring the output to be disconnected from the input source when the circuit is in shutdown.

## Inverting Topology

The LT8570/LT8570-1 can also work in a dual inductor inverting topology, as shown in Figure 2. The part's unique feedback pin allows for the inverting topology to be built by simply changing the connection of external components. This solution results in very low output voltage ripple due to the inductor L2 in series with the output. Abrupt changes in output capacitor current are eliminated because the output inductor delivers current to the output during both the off-time and the on-time of the LT8570/LT8570-1 switch.



**Figure 1. SEPIC Topology Allows for the Input to Span the Output Voltage. Coupled or Uncoupled Inductors Can Be Used. Follow Noted Phasing if Coupled**



**Figure 2. Dual Inductor Inverting Topology Results in Low Output Ripple. Coupled or Uncoupled Inductors Can Be Used. Follow Noted Phasing if Coupled**



## OPERATION

### Start-Up Operation

Several functions are provided to enable a very clean start-up for the LT8570/LT8570-1.

- First, the  $\overline{\text{SHDN}}$  pin voltage is monitored by an internal voltage reference to give a precise turn-on voltage level. An external resistor (or resistor divider) can be connected from the input power supply to the  $\overline{\text{SHDN}}$  pin to provide a user-programmable undervoltage lockout function.
- Second, the soft-start circuitry provides for a gradual ramp-up of the switch current. When the part is brought out of shutdown, the external SS capacitor is first discharged (providing protection against  $\overline{\text{SHDN}}$  pin glitches and slow ramping), then an integrated 280k resistor pulls the SS pin up to  $\sim 2.1\text{V}$ . By connecting an external capacitor to the SS pin, the voltage ramp rate on the pin can be set. Typical values for the soft-start capacitor range from 100nF to 1 $\mu\text{F}$ .
- Finally, the frequency foldback circuit reduces the switching frequency when the FBX pin is in a nominal range of 300mV to 920mV. This feature reduces the minimum

duty cycle that the part can achieve thus allowing better control of the switch current during start-up. When the FBX voltage is pulled outside of this range, the switching frequency returns to normal.

### Current Limit and Thermal Shutdown Operation

The LT8570/LT8570-1 have a current limit circuit not shown in the Block Diagram. The switch current is constantly monitored and not allowed to exceed the maximum switch current at a given duty cycle (see the Electrical Characteristics table). If the switch current reaches this value, the SR latch (SR1) is reset regardless of the state of the comparator (A1/A2). Also, not shown in the Block Diagram is the thermal shutdown circuit. If the temperature of the part exceeds approximately 165°C, the SR2 latch is set regardless of the state of the amplifier (A1/A2). When the part temperature falls below approximately 160°C, a full soft-start cycle will then be initiated. The current limit and thermal shutdown circuits protect the power switch as well as the external components connected to the LT8570/LT8570-1.

## APPLICATIONS INFORMATION

### Setting Output Voltage

The output voltage is set by connecting a resistor ( $R_{FBX}$ ) from  $V_{OUT}$  to the FBX pin.  $R_{FBX}$  is determined from the following equation:

$$R_{FBX} = \frac{|V_{OUT} - V_{FBX}|}{83.3\mu A}$$

where  $V_{FBX}$  is 1.204V (typical) for noninverting topologies (i.e., boost and SEPIC regulators) and 3mV (typical) for inverting topologies (see the Electrical Characteristics).

### Power Switch Duty Cycle

In order to maintain loop stability and deliver adequate current to the load, the power NPN (Q1 in the Block Diagram) cannot remain “on” for 100% of each clock cycle. The maximum allowable duty cycle is given by:

$$DC_{MAX} = \frac{(T_P - \text{Min Off Time})}{T_P} \cdot 100\%$$

where  $T_P$  is the clock period and Min Off Time (found in the Electrical Characteristics) is typically 100ns.

The application should be designed so that the operating duty cycle does not exceed  $DC_{MAX}$ .

The minimum allowable duty cycle is given by:

$$DC_{MIN} = \frac{\text{Min On Time}}{T_P} \cdot 100\%$$

where  $T_P$  is the clock period and Min On-Time is as shown in the Typical Performance Characteristics.

The application should be designed so that the operating duty cycle is at least  $DC_{MIN}$ .

Duty cycle equations for several common topologies are given below, where  $V_D$  is the diode forward voltage drop and  $V_{CESAT}$  is typically 250mV at 0.4A for the LT8570 and 250mV at 0.2A for the LT8570-1.

For the boost topology:

$$DC \cong \frac{V_{OUT} - V_{IN} + V_D}{V_{OUT} + V_D - V_{CESAT}}$$

For the SEPIC or dual inductor inverting topology (see Figure 1 and Figure 2):

$$DC \cong \frac{V_D + |V_{OUT}|}{V_{IN} + |V_{OUT}| + V_D - V_{CESAT}}$$

The LT8570/LT8570-1 can be used in configurations where the duty cycle is higher than  $DC_{MAX}$ , but it must be operated in the discontinuous conduction mode so that the effective duty cycle is reduced.

### Inductor Selection

**General Guidelines:** The high frequency operation of the LT8570/LT8570-1 allows for the use of small surface mount inductors. For high efficiency, choose inductors with high frequency core material, such as ferrite, to reduce core losses. To improve efficiency, choose inductors with more volume for a given inductance. The inductor should have low DCR (copper wire resistance) to reduce  $I^2R$  losses, and must be able to handle the peak inductor current without saturating. Note that in some applications, the current handling requirements of the inductor can be lower, such as in the SEPIC topology, where each inductor only carries a fraction of the total switch current. Multilayer or chip inductors usually do not have enough core area to support peak inductor currents in the 0.25A to 1A range. To minimize radiated noise, use a toroidal or shielded inductor. Note that the inductance of shielded types will drop more as current increases, and will saturate more easily. See Table 1 for a list of inductor manufacturers. Thorough lab evaluation is recommended to verify that the following guidelines properly suit the final application.

**Table 1. Inductor Manufacturers**

Coilcraft	LPS5030, MSS7341, LPS4018, LPD6235 and LPD5030 Series	www.coilcraft.com
Coiltronics	DR, DRQ, SD and SDQ Series	www.coiltronics.com
Sumida	CDRH8D58/LD, CDRH64B, and CDRH70D430MN Series	www.sumida.com
Würth	WE-PD, WE-DD, WE-TPC, WE-LHMI and WE-LQS Series	www.we-online.com

**Minimum Inductance:** Although there can be a trade-off with efficiency, it is often desirable to minimize board space by choosing smaller inductors. When choosing an inductor, there are two conditions that limit the minimum inductance: (1) providing adequate load current,

## APPLICATIONS INFORMATION

and (2) avoiding subharmonic oscillation. Choose an inductance that is high enough to meet both of these requirements.

**Adequate Load Current:** Small value inductors result in increased ripple currents and thus, due to the limited peak switch current, decrease the average current that can be provided to a load ( $I_{OUT}$ ). In order to provide adequate load current, L should be at least:

$$L_{BOOST} > \frac{DC \cdot V_{IN}}{2 \cdot f \cdot \left( I_{LIM} - \frac{|V_{OUT}| \cdot I_{OUT}}{V_{IN} \cdot \eta} \right)}$$

for boost, topologies, or:

$$L_{DUAL} > \frac{DC \cdot V_{IN}}{2 \cdot f \cdot \left( I_{LIM} - \frac{|V_{OUT}| \cdot I_{OUT}}{V_{IN} \cdot \eta} - I_{OUT} \right)}$$

for the SEPIC and inverting topologies.

where:

$L_{BOOST} = L1$  for boost topologies (see Figure 15)

$L_{DUAL} = L1 = L2$  for coupled dual inductor topologies (see Figure 16 and Figure 17)

$L_{DUAL} = L1 || L2$  for uncoupled dual inductor topologies (see Figure 16 and Figure 17)

DC = switch duty cycle (see previous section)

$I_{LIM}$  = switch current limit, typically about 0.6A for LT8570 and 0.3A for LT8570-1 at 50% duty cycle (see the Typical Performance Characteristics section).

$\eta$  = power conversion efficiency (typically 85% for boost and 83% for dual inductor topologies at high currents).

f = switching frequency

$I_{OUT}$  = maximum load current

Negative values of L indicate that the output load current  $I_{OUT}$  exceeds the switch current limit capability of the LT8570/LT8570-1.

**Avoiding Subharmonic Oscillations:** The LT8570/LT8570-1's internal slope compensation circuit can prevent subharmonic oscillations that can occur when the duty cycle

is greater than 50%, provided that the inductance exceeds a minimum value. In applications that operate with duty cycles greater than 50%, the inductance must be at least:

$$L_{MIN} > \frac{V_{IN}}{k_{SC} \cdot (DC - 300ns \cdot f) \cdot f} \cdot \frac{2 \cdot DC - 1}{1 - DC}$$

$L_{MIN} = L1$  for boost topologies (see Figure 15)

$L_{MIN} = L1 = L2$  for coupled dual inductor topologies (see Figure 16 and Figure 17)

$L_{MIN} = L1 || L2$  for uncoupled dual inductor topologies (see Figure 16 and Figure 17)

$k_{SC} = 0.6$  for LT8570 and 0.3 for LT8570-1

**Maximum Inductance:** Excessive inductance can reduce current ripple to levels that are difficult for the current comparator (A3 in the Block Diagram) to cleanly discriminate, thus causing duty cycle jitter and/or poor regulation. The maximum inductance can be calculated by:

$$L_{MAX} = \frac{V_{IN} - V_{CESAT}}{I_{MIN-RIPPLE}} \cdot \frac{DC}{f}$$

where

$L_{MIN} = L1$  for boost topologies (see Figure 15)

$L_{MIN} = L1 = L2$  for coupled dual inductor topologies (see Figure 16 and Figure 17)

$L_{MIN} = L1 || L2$  for uncoupled dual inductor topologies (see Figure 16 and Figure 17)

$I_{MIN-RIPPLE}$  = typically 40mA for LT8570 and 20mA for LT8570-1

**Current Rating:** Finally, the inductor(s) must have a rating greater than its peak operating current to prevent inductor saturation resulting in efficiency loss. In steady state, the peak input inductor current (continuous conduction mode only) is given by:

$$I_{L1-PEAK} = \frac{|V_{OUT}| \cdot I_{OUT}}{V_{IN} \cdot \eta} + \frac{V_{IN} \cdot DC}{2 \cdot L1 \cdot f}$$

for the boost, SEPIC and dual inductor inverting topologies.

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For dual inductor topologies, the peak output inductor current is given by:

$$I_{L2-PEAK} = I_{OUT} + \frac{|V_{OUT}| \cdot (1 - DC)}{2 \cdot L_2 \cdot f}$$

For the dual inductor topologies, the total peak current is:

$$I_{L-PEAK} = I_{OUT} \left( 1 + \frac{|V_{OUT}|}{\eta \cdot V_{IN}} \right) + \frac{V_{IN} \cdot DC}{2 \cdot L \cdot f}$$

Note: Peak inductor current is limited by the switch current limit. Refer to the Electrical Characteristics table and to the Switch Current Limit vs Duty Cycle plot in the Typical Performance Characteristics.

### Capacitor Selection

Low ESR (equivalent series resistance) capacitors should be used at the output to minimize the output ripple voltage. Multilayer ceramic capacitors are an excellent choice, as they have an extremely low ESR and are available in very small packages. X5R or X7R dielectrics are preferred, as these materials retain their capacitance over wider voltage and temperature ranges. For LT8570, a 0.22μF to 4.7μF and for LT8570-1, a 0.1μF to 2.2μF output capacitor is sufficient for most applications. Always use a capacitor with a sufficient voltage rating. Although many ceramic capacitors have greatly reduced capacitance at the desired output voltage, ceramic capacitors with larger case sizes are less sensitive to applied voltage. Solid tantalum or OS-CON capacitors can be used, but they will occupy more board area than a ceramic and will have a higher ESR with greater output ripple.

Ceramic capacitors also make a good choice for the input decoupling capacitor, which should be placed as closely as possible to the  $V_{IN}$  pin of the LT8570/LT8570-1 as well as to the inductor connected to the input of the power path. If it is not possible to optimally place a single input capacitor, then use one at the  $V_{IN}$  pin of the chip ( $C_{VIN}$ ) and one at the  $V_{IN}$  side of the inductor ( $C_{PWR}$ ). See equations in Table 4, Table 5 and Table 6 for sizing information. For LT8570, a 0.47μF to 1μF and for LT8570-1, a 0.22μF to 0.47μF input capacitor is sufficient for most applications.

Table 2 shows a list of several ceramic capacitor manufacturers. Consult the manufacturers for detailed information on their entire selection of ceramic parts.

**Table 2. Ceramic Capacitor Manufacturers**

Kemet	<a href="http://www.kemet.com">www.kemet.com</a>
Murata	<a href="http://www.murata.com">www.murata.com</a>
Taiyo Yuden	<a href="http://www.t-yuden.com">www.t-yuden.com</a>
TDK	<a href="http://www.tdk.com">www.tdk.com</a>

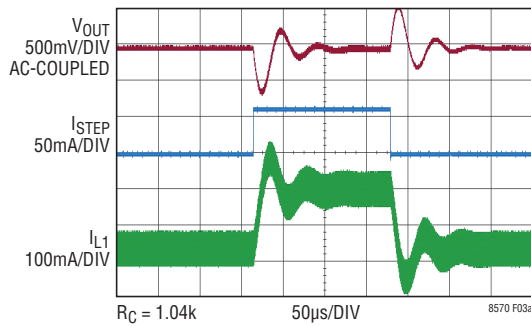
### Compensation—Adjustment

To compensate the feedback loop of the LT8570/LT8570-1, a series resistor-capacitor network in parallel with a single capacitor should be connected from the VC pin to GND. For most applications, the series capacitor should be in the range of 470pF to 2.2nF with 1nF being a good starting value. The parallel capacitor should range in value from 10pF to 100pF with 47pF a good starting value. The compensation resistor,  $R_C$ , is usually in the range of 5k to 50k. A good technique to compensate a new application is to use a 100kΩ potentiometer in place of series resistor  $R_C$ . With the series capacitor and parallel capacitor at 1nF and 47pF respectively, adjust the potentiometer while observing the transient response and the optimum value for  $R_C$  can be found. Figure 3 (3a to 3c) illustrates this process for the circuit of Figure 4 with a load current stepped between 30mA and 90mA. Figure 3a shows the transient response with  $R_C$  equal to 1.04k. The phase margin is poor, as evidenced by the excessive ringing in the output voltage and inductor current. In Figure 3b, the value of  $R_C$  is increased to 2.09k, which results in a more damped response. Figure 3c shows the results when  $R_C$  is increased further to 6.19k. The transient response is nicely damped and the compensation procedure is complete.

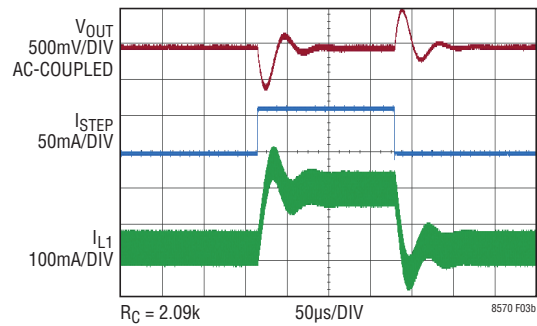
### Compensation—Theory

Like all other current mode switching regulators, the LT8570/LT8570-1 need to be compensated for stable and efficient operation. Two feedback loops are used in the LT8570/LT8570-1 — a fast current loop which does not require compensation, and a slower voltage loop which does. Standard bode plot analysis can be used to understand and adjust the voltage feedback loop.

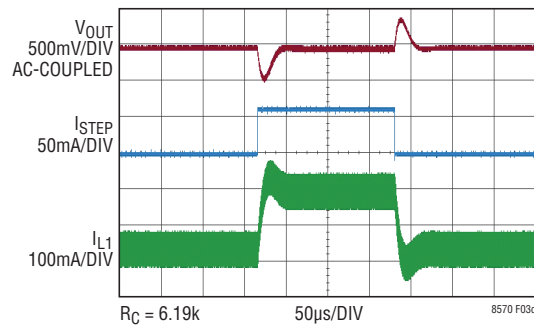
# APPLICATIONS INFORMATION



(3a) Transient Response Shows Excessive Ringing



(3b) Transient Response Is Better



(3c) Transient Response Is Well Damped

Figure 3. Transient Response

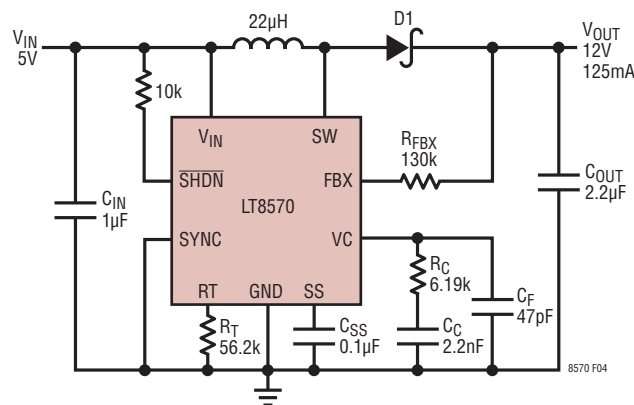
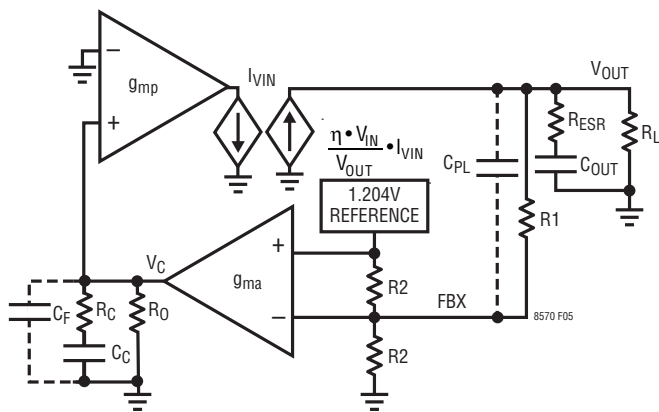


Figure 4. 1.5MHz, 5V to 12V Boost Converter

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As with any feedback loop, identifying the gain and phase contribution of the various elements in the loop is critical. Figure 5 shows the key equivalent elements of a boost converter. Because of the fast current control loop, the power stage of the IC, inductor and diode have been replaced by a combination of the equivalent transconductance amplifier  $g_{mp}$  and the current controlled current source which converts  $I_{VIN}$  to  $(\eta V_{IN}/V_{OUT}) \cdot I_{VIN}$ .  $g_{mp}$  acts as a current source where the peak input current,  $I_{VIN}$ , is proportional to the VC voltage.  $\eta$  is the efficiency of the switching regulator, and is typically about 85%.

Note that the maximum output currents of  $g_{mp}$  and  $g_{ma}$  are finite. The limits for  $g_{mp}$  are in the Electrical Characteristics section (switch current limit), and  $g_{ma}$  is nominally limited to about  $+15\mu A$  and  $-17\mu A$ .



$C_C$ : COMPENSATION CAPACITOR  
 $C_{OUT}$ : OUTPUT CAPACITOR  
 $C_{PL}$ : PHASE LEAD CAPACITOR  
 $C_F$ : HIGH FREQUENCY FILTER CAPACITOR  
 $g_{ma}$ : TRANSCONDUCTANCE AMPLIFIER INSIDE IC  
 $g_{mp}$ : POWER STAGE TRANSCONDUCTANCE AMPLIFIER  
 $R_C$ : COMPENSATION RESISTOR  
 $R_L$ : OUTPUT RESISTANCE DEFINED AS  $V_{OUT}$  DIVIDED BY  $I_{LOAD(MAX)}$   
 $R_0$ : OUTPUT RESISTANCE OF  $g_{ma}$   
 $R1, R2$ : FEEDBACK RESISTOR DIVIDER NETWORK  
 $R_{ESR}$ : OUTPUT CAPACITOR ESR  
 $\eta$ : CONVERTER EFFICIENCY (~85% AT HIGHER CURRENTS)

Figure 5. Boost Converter Equivalent Model

From Figure 5, the DC gain, poles and zeros can be calculated as follows:

DC Gain:

(Breaking Loop at FBX Pin)

$$A_{DC} = A_{OL}(0) = \frac{\partial V_C}{\partial V_{FBX}} \cdot \frac{\partial I_{VIN}}{\partial V_C} \cdot \frac{\partial V_{OUT}}{\partial I_{VIN}} \cdot \frac{\partial V_{FBX}}{\partial V_{OUT}} =$$

$$(g_{ma} \cdot R_0) \cdot g_{mp} \cdot \left( \eta \cdot \frac{V_{IN}}{V_{OUT}} \cdot \frac{R_L}{2} \right) \cdot \frac{0.5R_2}{R1 + 0.5R2}$$

$$\text{Output Pole: } P1 = \frac{2}{2 \cdot \pi \cdot R_L \cdot C_{OUT}}$$

$$\text{Error Amp Pole: } P2 = \frac{1}{2 \cdot \pi \cdot [R_0 + R_C] \cdot C_C}$$

$$\text{Error Amp Zero: } Z1 = \frac{1}{2 \cdot \pi \cdot R_C \cdot C_C}$$

$$\text{ESR Zero: } Z2 = \frac{1}{2 \cdot \pi \cdot R_{ESR} \cdot C_{OUT}}$$

$$\text{RHP Zero: } Z3 = \frac{V_{IN}^2 \cdot R_L}{2 \cdot \pi \cdot V_{OUT}^2 \cdot L}$$

$$\text{High Frequency Pole: } P3 > \frac{f_S}{3}$$

$$\text{Phase Lead Zero: } Z4 = \frac{1}{2 \cdot \pi \cdot R1 \cdot C_{PL}}$$

$$\text{Phase Lead Pole: } P4 = \frac{1}{2 \cdot \pi \cdot \frac{R1 \cdot R2}{R1 + \frac{R2}{2}} \cdot C_{PL}}$$

Error Amp Filter Pole:

$$P5 = \frac{1}{2 \cdot \pi \cdot \frac{R_C \cdot R_0}{R_C + R_0} \cdot C_F}, C_F < \frac{C_C}{10}$$



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The current mode zero (Z3) is a right-half plane zero which can be an issue in feedback control design, but is manageable with proper external component selection.

Using the circuit in Figure 4 as an example, Table 3 shows the parameters used to generate the bode plot shown in Figure 6.

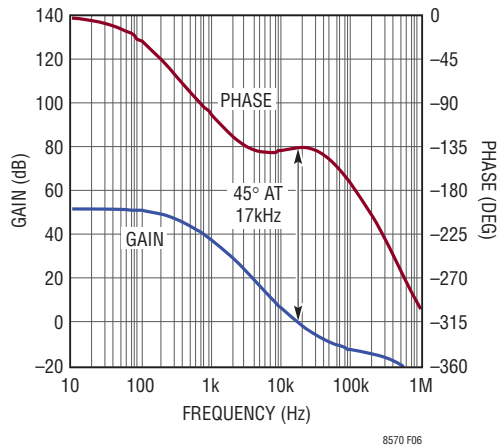


Figure 6. Bode Plot for Example Boost Converter

Table 3. Bode Plot Parameters

PARAMETER	VALUE	UNITS	COMMENT
R <sub>L</sub>	96	Ω	Application Specific
C <sub>OUT</sub>	2.2	μF	Application Specific
R <sub>ESR</sub>	10	mΩ	Application Specific
R <sub>O</sub>	300	kΩ	Not Adjustable
C <sub>C</sub>	2200	pF	Adjustable
C <sub>F</sub>	47	pF	Optional/Adjustable
C <sub>PL</sub>	0	pF	Optional/Adjustable
R <sub>C</sub>	6.19	kΩ	Adjustable
R <sub>1</sub>	130	kΩ	Adjustable
R <sub>2</sub>	14.5	kΩ	Not Adjustable
V <sub>OUT</sub>	12	V	Application Specific
V <sub>IN</sub>	5	V	Application Specific
g <sub>ma</sub>	200	μmho	Not Adjustable
g <sub>mp</sub>	7	mho	Not Adjustable
L	22	μH	Application Specific
f <sub>S</sub>	1.5	MHz	Adjustable

In Figure 6, the phase is  $-135^\circ$  when the gain reaches 0dB giving a phase margin of  $45^\circ$ . The crossover frequency is 17kHz, which is more than three times lower than the frequency of the RHP zero to achieve adequate phase margin.

### Diode Selection

Schottky diodes, with their low forward-voltage drops and fast switching speeds, are recommended for use with the LT8570/LT8570-1. For applications where  $V_R$  (see Tables 4, 5 and 6)  $< 40V$ , the Diodes, Inc. PD3S140 is a good choice. Where  $V_R > 40V$ , the Diodes Inc. DFLS1100 works well. These diodes are rated to handle an average forward current of 1A.

### Oscillator

The operating frequency of the LT8570/LT8570-1 can be set by the internal free-running oscillator. When the SYNC pin is driven low ( $< 0.4V$ ), the frequency of operation is set by a resistor from RT to ground. An internally trimmed timing capacitor resides inside the IC. The oscillator frequency is calculated using the following formula:

$$f_{osc} = \frac{85.5}{(R_T + 1)}$$

where  $f_{osc}$  is in MHz and  $R_T$  is in kΩ. Conversely,  $R_T$  (in kΩ) can be calculated from the desired frequency (in MHz) using:

$$R_T = \frac{85.5}{f_{osc}} - 1$$

### Clock Synchronization

The operating frequency of the LT8570/LT8570-1 can be synchronized to an external clock source. To synchronize to the external source, simply provide a digital clock signal into the SYNC pin. The LT8570/LT8570-1 will operate at the SYNC clock frequency. The LT8570/LT8570-1 will revert to the internal free-running oscillator clock after SYNC is driven low for a few free-running clock periods.

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Driving SYNC high for an extended period of time effectively stops the operating clock and prevents latch SR1 from becoming set (see the Block Diagram). As a result, the switching operation of the LT8570/LT8570-1 will stop.

The duty cycle of the SYNC signal must be between 35% and 65% for proper operation. Also, the frequency of the SYNC signal must meet the following two criteria:

- (1) SYNC may not toggle outside the frequency range of 200kHz to 1.5MHz unless it is stopped low to enable the free-running oscillator.
- (2) The SYNC frequency can always be higher than the free-running oscillator frequency,  $f_{OSC}$ , but should not be less than 25% below  $f_{OSC}$ .

### Operating Frequency Selection

There are several considerations in selecting the operating frequency of the converter. The first is staying clear of sensitive frequency bands, which cannot tolerate any spectral noise. For example, in products incorporating RF communications, the 455kHz IF frequency is sensitive to any noise, therefore switching above 600kHz is desired. Some communications have sensitivity to 1.1MHz, and in that case, a 1.5MHz switching converter frequency may be employed. The second consideration is the physical size of the converter. As the operating frequency goes up, the inductor and filter capacitors go down in value and size. The trade-off is efficiency, since the switching losses due to NPN base charge (see Thermal Calculations), Schottky diode charge, and other capacitive loss terms increase proportionally with frequency.

### Soft-Start

The LT8570/LT8570-1 contain a soft-start circuit to limit peak switch currents during start-up. High start-up current is inherent in switching regulators in general since the feedback loop is saturated due to  $V_{OUT}$  being far from its final value. The regulator tries to charge the output capacitor as quickly as possible, which results in large peak currents.

The start-up current can be limited by connecting an external capacitor (typically 100nF to 1 $\mu$ F) to the SS pin.

This capacitor is slowly charged to ~2.1V by an internal 280k resistor once the part is activated. SS pin voltages below ~1.1V reduce the internal current limit. Thus, the gradual ramping of the SS voltage also gradually increases the current limit as the capacitor charges. This, in turn, allows the output capacitor to charge gradually toward its final value while limiting the start-up current.

In the event of a commanded shutdown or lockout ( $\overline{SHDN}$  pin), internal undervoltage lockout (UVLO) or a thermal lockout, the soft-start capacitor is automatically discharged to ~200mV before charging resumes, thus assuring that the soft-start occurs after every reactivation of the chip.

### Shutdown

The  $\overline{SHDN}$  pin is used to enable or disable the chip. For most applications,  $\overline{SHDN}$  can be driven by a digital logic source. Voltages above 1.4V enable normal active operation. Voltages below 300mV will shutdown the chip, resulting in extremely low quiescent current.

While the  $\overline{SHDN}$  voltage transitions through the lockout voltage range (0.3V to 1.21V) the power switch is disabled and the SR2 latch is set (see the Block Diagram). This causes the soft-start capacitor to begin discharging, which continues until the capacitor is discharged and active operation is enabled. Although the power switch is disabled,  $\overline{SHDN}$  voltages in the lockout range do not necessarily reduce quiescent current until the  $\overline{SHDN}$  voltage is near or below the shutdown threshold.

Also note that  $\overline{SHDN}$  can be driven above  $V_{IN}$  or  $V_{OUT}$  as long as the  $\overline{SHDN}$  voltage is limited to less than 40V.

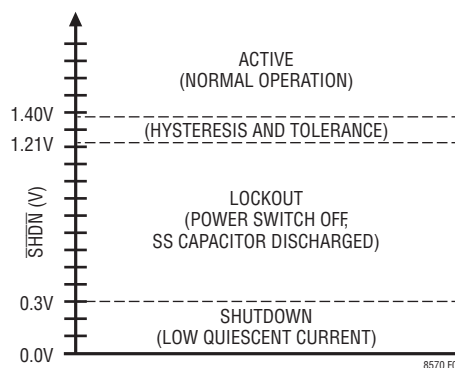


Figure 7. Chip States vs  $\overline{SHDN}$  Voltage



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### Configurable Undervoltage Lockout

Figure 8 shows how to configure an undervoltage lockout (UVLO) for the LT8570/LT8570-1. Typically, UVLO is used in situations where the input supply is current-limited, has a relatively high source resistance, or ramps up/down slowly. A switching regulator draws constant power from the source, so source current increases as source voltage drops. This looks like a negative resistance load to the source and can cause the source to current-limit or latch low under low source voltage conditions. UVLO prevents the regulator from operating at source voltages where these problems might occur.

The shutdown pin comparator has voltage hysteresis with typical thresholds of 1.31V (rising) and 1.27V (falling). Resistor  $R_{UVLO2}$  is optional.  $R_{UVLO2}$  can be included to reduce the overall UVLO voltage variation caused by variations in  $\overline{\text{SHDN}}$  pin current (see the Electrical Characteristics). A good choice for  $R_{UVLO2}$  is  $\leq 10k \pm 1\%$ . After choosing a value for  $R_{UVLO2}$ ,  $R_{UVLO1}$  can be determined from either of the following:

$$R_{UVLO1} = \frac{V_{IN}^+ - 1.31V}{\left(\frac{1.31V}{R_{UVLO2}}\right) + 12\mu A}$$

or

$$R_{UVLO1} = \frac{V_{IN}^- - 1.27V}{\left(\frac{1.27V}{R_{UVLO2}}\right) + 12\mu A}$$

where  $V_{IN}^+$  and  $V_{IN}^-$  are the  $V_{IN}$  voltages when rising or falling, respectively.

For example, to disable the LT8570/LT8570-1 for  $V_{IN}$  voltages below 3.5V using the single resistor configuration, choose:

$$R_{UVLO1} = \frac{3.5V - 1.27V}{\left(\frac{1.27V}{\infty}\right) + 12\mu A} = 187k$$

To activate the LT8570/LT8570-1 for  $V_{IN}$  voltages greater than 4.5V using the double resistor configuration, choose  $R_{UVLO2} = 10k$  and:

$$R_{UVLO1} = \frac{4.5V - 1.31V}{\left(\frac{1.31V}{10k}\right) + 12\mu A} = 22.1k$$

### Internal Undervoltage Lockout

The LT8570/LT8570-1 monitor the  $V_{IN}$  supply voltage in case  $V_{IN}$  drops below a minimum operating level (typically about 2.35V). When  $V_{IN}$  is detected low, the power switch is deactivated, and while sufficient  $V_{IN}$  voltage persists, the soft-start capacitor is discharged. After  $V_{IN}$  is detected high, the power switch will be reactivated and the soft-start capacitor will begin charging.

### Thermal Considerations

For the LT8570/LT8570-1 to deliver their full output power, it is imperative that a good thermal path be provided to dissipate the heat generated within the package. This is accomplished by taking advantage of the thermal pad on the underside of the IC. It is recommended that multiple vias in the printed circuit board be used to conduct heat away from the IC and into a copper plane with as much area as possible.

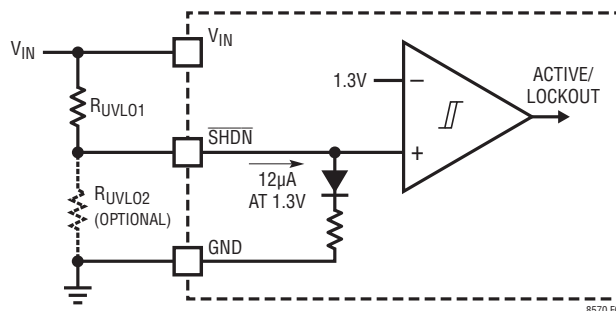


Figure 8. Configurable UVLO

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### Thermal Lockout

If the die temperature reaches approximately 165°C, the part will go into thermal lockout, the power switch will be turned off and the soft-start capacitor will be discharged. The part will be enabled again when the die temperature has dropped by ~5°C (nominal).

### Thermal Calculations

Power dissipation in the LT8570/LT8570-1 chip comes from four primary sources: switch  $I^2R$  loss, NPN base drive (AC), NPN base drive (DC), and additional input current. The following formulas can be used to approximate the power losses. These formulas assume continuous mode operation, so they should not be used for calculating efficiency in discontinuous mode or at light load currents.

$$\text{Average Input Current: } I_{IN} = \frac{V_{OUT} \cdot I_{OUT}}{V_{IN} \cdot \eta}$$

$$\text{Switch Conduction Loss: } P_{SW} = (DC)(I_{IN})(V_{SW})$$

$$\text{Base Drive Loss (AC): } P_{BAC} = 20\text{ns}(I_{IN})(V_{OUT})(f)$$

$$\text{Base Drive Loss (DC): } P_{BDC} = \frac{(V_{IN})(I_{IN})(DC)}{40}$$

$$\text{Input Power Loss: } P_{INP} = 4.5\text{mA}(V_{IN})$$

where:

$V_{SW}$  = switch on voltage (see Typical Performance Characteristics for Switch Saturation Voltage)

DC = duty cycle (see the Power Switch Duty Cycle section for formulas)

$\eta$  = power conversion efficiency (typically 85% at high currents)

Example: LT8570 in boost configuration,  $V_{IN} = 5\text{V}$ ,  $V_{OUT} = 12\text{V}$ ,  $I_{OUT} = 0.1\text{A}$ ,  $f = 1.25\text{MHz}$ ,  $V_D = 0.5\text{V}$ :

$$I_{IN} = 0.28\text{A}$$

$$DC = 62.0\%$$

$$P_{SW} = 32\text{mW}$$

$$P_{BAC} = 85\text{mW}$$

$$P_{BDC} = 22\text{mW}$$

$$P_{INP} = 23\text{mW}$$

$$\text{Total LT8570 power dissipation } (P_{TOT}) = 161\text{mW}$$

Thermal resistance for the LT8570/LT8570-1 is influenced by the presence of internal, topside or backside planes. To calculate die temperature, use the appropriate thermal resistance number and add in worst-case ambient temperature:

$$T_J = T_A + \theta_{JA} \cdot P_{TOT}$$

where  $T_J$  = junction temperature,  $T_A$  = ambient temperature, and  $\theta_{JA}$  is the thermal resistance from the silicon junction to the ambient air.

The published  $\theta_{JA}$  value is 43°C/W for the 3mm × 3mm DFN package and 35°C/W to 40°C/W for the MSOP exposed pad package. In practice, lower  $\theta_{JA}$  values can be obtained if the board layout uses ground as a heat sink. For instance, thermal resistances of 34.7°C/W for the DFN package and 22.5°C/W for the MSOP package were obtained on a board designed with large ground planes.

### $V_{IN}$ Ramp Rate

While initially powering a switching converter application, the  $V_{IN}$  ramp rate should be limited. High  $V_{IN}$  ramp rates can cause excessive inrush currents in the passive components of the converter. This can lead to current and/or voltage overstress and may damage the passive components or the chip. Ramp rates less than 500mV/μs, depending on component parameters, will generally prevent these issues. Also, be careful to avoid hot-plugging. Hot-plugging occurs when an active voltage supply is “instantly” connected or switched to the input of the converter. Hot-plugging results in very fast input ramp rates and is not recommended. Finally, for more information, refer to Linear application note AN88, which discusses voltage overstress that can occur when an inductive source impedance is hot-plugged to an input pin bypassed by ceramic capacitors.

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### Layout Hints

As with all high frequency switchers, when considering layout, care must be taken to achieve optimal electrical, thermal and noise performance. One will not get advertised performance with a careless layout. For maximum efficiency, switch rise and fall times are typically in the 10ns to 20ns range. To prevent noise, both radiated and conducted, the high speed switching current path, shown in Figure 9, must be kept as short as possible. This is implemented in the suggested layout of a boost configuration in Figure 10. Shortening this path will also reduce the parasitic trace inductance. At switch-off, this parasitic inductance produces a flyback spike across the LT8570/LT8570-1 switch. When operating at higher currents and output voltages, with poor layout, this spike can generate voltages across the LT8570/LT8570-1 that may exceed the absolute maximum rating. A ground plane should also be used under the switcher circuitry to prevent interplane coupling and overall noise.

The VC and FBX components should be kept as far away as practical from the switch node, while still remaining close to the chip. The ground for these components should be separated from the switch current path. Failure to do so can result in poor stability or subharmonic oscillation.

Board layout also has a significant effect on thermal resistance. The exposed package ground pad is the copper plate that runs under the LT8570/LT8570-1 die. This is

a good thermal path for heat out of the package. Soldering the pad onto the board reduces die temperature and increases the power capability of the LT8570/LT8570-1. Provide as much copper area as possible around this pad. Adding multiple feedthroughs around the pad to the ground plane will also help. Figure 10 and Figure 11 show the recommended component placement for the boost and SEPIC configurations, respectively.

### Layout Hints for Inverting Topology

Figure 12 shows recommended component placement for the dual inductor inverting topology. Input bypass capacitor, C1, should be placed close to the LT8570/LT8570-1, as shown. The load should connect directly to the output capacitor, C2, for best load regulation. The local ground may be tied into the system ground plane at the C3 ground terminal.

The cut ground copper at D1's cathode is essential to obtain low noise. This important layout issue arises due to the chopped nature of the currents flowing in Q1 and D1. If they are both tied directly to the ground plane before being combined, switching noise will be introduced into the ground plane. It is almost impossible to get rid of this noise, once present in the ground plane. The solution is to tie D1's cathode to the ground pin of the LT8570/LT8570-1 before the combined currents are dumped in the ground plane as drawn in Figure 12, Figure 13 and Figure 14. This single layout technique can virtually eliminate high frequency "spike" noise, so often present on switching regulator outputs.

### Differences from LT3580

LT8570/LT8570-1 are very similar to LT3580. However, LT8570/LT8570-1 do deviate from LT3580 in a few areas:

- 65V, 0.5A switch for LT8570
- 65V, 0.25A switch for LT8570-1
- 40V  $V_{IN}$  and  $\overline{SHDN}$  absolute maximum rating
- FB renamed to FBX
- 5V FBX absolute maximum rating

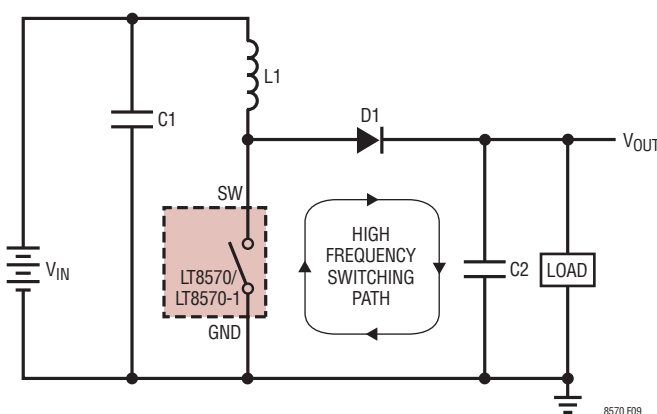
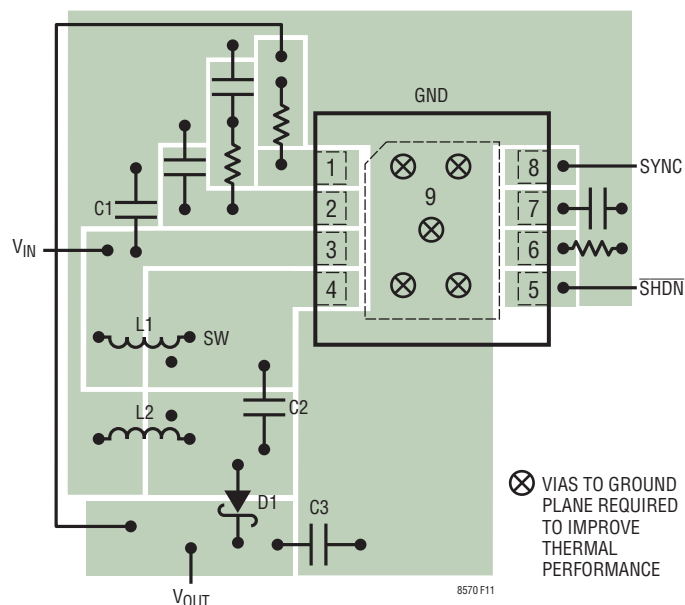


Figure 9. High Speed "Chopped" Switching Path for Boost Topology



**Figure 11. Suggested Component Placement for SEPIC Topology (Both DFN And MSOP Packages. Not to Scale). Pin 9 (Exposed Pad) Must Be Soldered Directly to the Local Ground Plane for Adequate Thermal Performance. Multiple Vias to Additional Ground Planes Will Improve Thermal Performance**



# APPLICATIONS INFORMATION

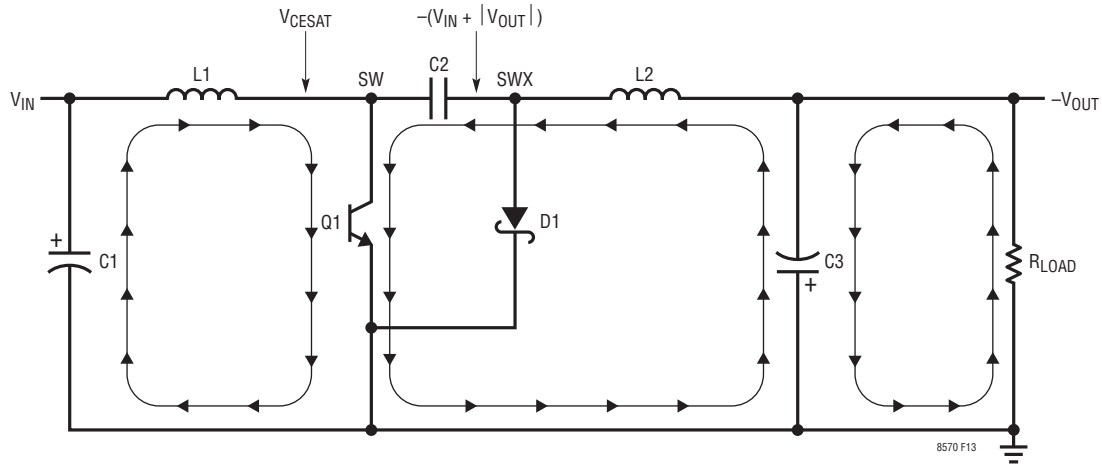


Figure 13. Switch-On Phase of an Inverting Converter. L1 and L2 Have Positive  $di/dt$

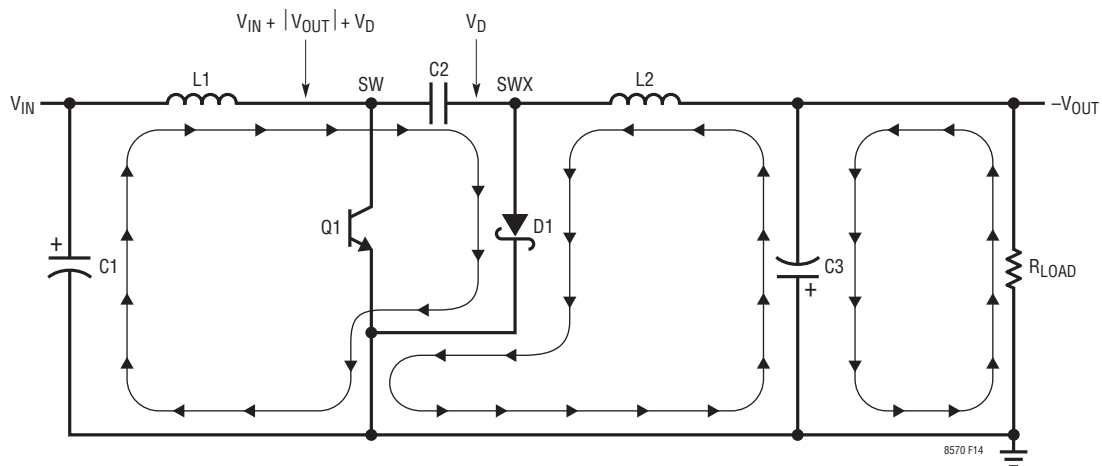
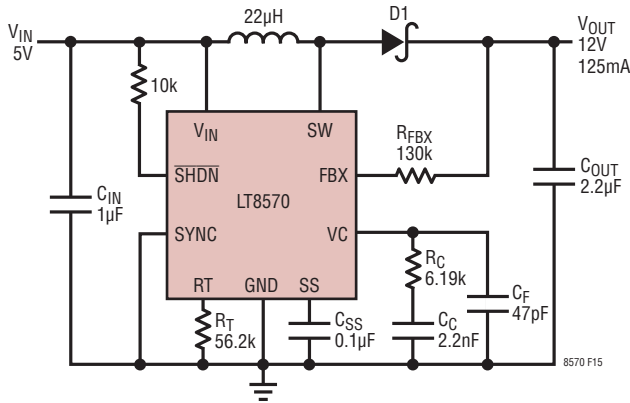


Figure 14. Switch-Off Phase of an Inverting Converter. L1 and L2 Currents Have Negative  $di/dt$

## APPLICATIONS INFORMATION

### BOOST CONVERTER COMPONENT SELECTION



**Figure 15. Boost Converter: The Component Values Given Are Typical Values for a 1.5MHz, 5V to 12V Boost**

The LT8570/LT8570-1 can be configured as a boost converter as in Figure 15. This topology allows for positive output voltages that are higher than the input voltage. A single feedback resistor sets the output voltage. For output voltages higher than 60V, see the Charge Pump Aided Regulators section.

For a desired output voltage over a given input voltage range, Table 4 is a step-by-step set of equations to calculate component values for the LT8570/LT8570-1 when operating as a boost converter. Refer to the Applications Information section for further information on the design equations presented in Table 4.

#### Variable Definitions:

$V_{IN}$  = Input Voltage

$V_{OUT}$  = Output Voltage

DC = Power Switch Duty Cycle

$f_{OSC}$  = Switching Frequency

$I_{OUT}$  = Maximum Average Output Current

$I_{RIPPLE}$  = Inductor Ripple Current

$I_{RTYP}$  = 150mA for LT8570 and 75mA for LT8570-1

$k_{SC}$  = 0.6A for LT8570 and 0.3A for LT8570-1

$I_{RMIN}$  = 0.04A for LT8570 and 0.02A for LT8570-1

$I_{LIM}$  = 0.5A for LT8570 and 0.25A for LT8570-1

**Table 4. Boost Design Equations**

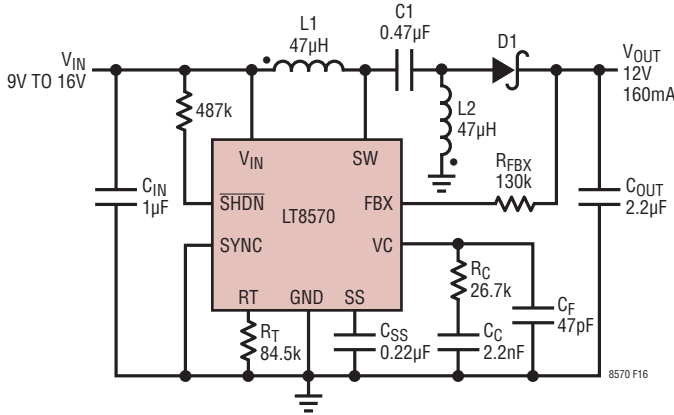
	PARAMETERS/EQUATIONS
<b>Step 1: Inputs</b>	Pick $V_{IN}$ , $V_{OUT}$ , and $f_{OSC}$ to calculate equations below
<b>Step 2: DC</b>	$DC_{MAX} = \frac{V_{OUT} - V_{IN(MIN)} + 0.5V}{V_{OUT} + 0.5V - 0.4V}$ $DC_{MIN} = \frac{V_{OUT} - V_{IN(MAX)} + 0.5V}{V_{OUT} + 0.5V - 0.4V}$
<b>Step 3: L1</b>	$L_{TYP} = \frac{(V_{IN(MIN)} - 0.4V) \cdot DC_{MAX}}{f_{OSC} \cdot I_{RTYP}} \quad (1)$ $L_{MIN} = \frac{(V_{IN(MIN)} - 0.4V) \cdot (2 \cdot DC_{MAX} - 1)}{k_{SC} \cdot (DC_{MAX} - 300ns \cdot f_{OSC}) \cdot f_{OSC} \cdot (1 - DC_{MAX})} \quad (2)$ $L_{MAX1} = \frac{(V_{IN(MIN)} - 0.4V) \cdot DC_{MAX}}{f_{OSC} \cdot I_{RMIN}} \quad (3)$ $L_{MAX2} = \frac{(V_{IN(MAX)} - 0.4V) \cdot DC_{MIN}}{f_{OSC} \cdot I_{RMIN}} \quad (4)$ <ul style="list-style-type: none"> <li>Solve equations 1 to 4 for a range of L values</li> <li>The minimum of the L value range is the higher of <math>L_{TYP}</math> and <math>L_{MIN}</math></li> <li>The maximum of the L value range is the lower of <math>L_{MAX1}</math> and <math>L_{MAX2}</math></li> </ul>
<b>Step 4: I<sub>RIPPLE</sub></b>	$I_{RIPPLE(MIN)} = \frac{(V_{IN(MIN)} - 0.4V) \cdot DC_{MAX}}{f_{OSC} \cdot L_1}$ $I_{RIPPLE(MAX)} = \frac{(V_{IN(MAX)} - 0.4V) \cdot DC_{MIN}}{f_{OSC} \cdot L_1}$
<b>Step 5: I<sub>OUT</sub></b>	$I_{OUT(MIN)} = \left( I_{LIM} - \frac{I_{RIPPLE(MIN)}}{2} \right) \cdot (1 - DC_{MAX})$ $I_{OUT(MAX)} = \left( I_{LIM} - \frac{I_{RIPPLE(MAX)}}{2} \right) \cdot (1 - DC_{MIN})$
<b>Step 6: D1</b>	$V_R > V_{OUT}$ ; $I_{AVG} > I_{OUT}$
<b>Step 7: C<sub>OUT</sub></b>	$C_{OUT} \geq \frac{I_{OUT} \cdot DC_{MAX}}{f_{OSC} \cdot 0.005 \cdot V_{OUT}}$
<b>Step 8: C<sub>IN</sub></b>	$C_{IN} \geq C_{VIN} + C_{PWR} \geq \frac{I_{LIM} \cdot DC_{MAX}}{40 \cdot f_{OSC} \cdot 0.005 \cdot V_{IN(MIN)}} + \frac{I_{RIPPLE(MAX)}}{8 \cdot f_{OSC} \cdot 0.005 \cdot V_{IN(MAX)}}$ <ul style="list-style-type: none"> <li>Refer to the Capacitor Selection Section for definition of <math>C_{VIN}</math> and <math>C_{PWR}</math></li> </ul>
<b>Step 9: R<sub>FBK</sub></b>	$R_{FBK} = \frac{V_{OUT} - 1.204V}{83.3\mu A}$
<b>Step 10: R<sub>T</sub></b>	$R_T = \frac{85.5}{f_{OSC}} - 1; f_{OSC} \text{ in MHz and } R_T \text{ in k}\Omega$

**Note 1:** This table uses 0.5A and 0.25A for the peak switch current. Refer to the Electrical Characteristics Table and Typical Performance Characteristics plots for the peak switch current at an operating duty cycle.

**Note 2:** The final values for  $C_{OUT}$  and  $C_{IN}$  may deviate from the previous equations in order to obtain desired load transient performance.

## APPLICATIONS INFORMATION

### SEPIC CONVERTER COMPONENT SELECTION (COUPLED OR UNCOUPLED INDUCTORS)



**Figure 16. SEPIC Converter: The Component Values and Voltages Given Are Typical Values for a 1MHz, 9V-16V to 12V SEPIC Converter Using Coupled Inductors**

Figure 16 shows the LT8570 configured as a SEPIC. This topology allows for positive output voltages that are lower, equal or higher than the input voltage. Output disconnect is inherent to the SEPIC topology, meaning no DC path exists between the input and output due to capacitor C1.

For a desired output voltage over a given input voltage range, Table 5 is a step-by-step set of equations to calculate component values for the LT8570/LT8570-1 when operating as a SEPIC converter. Refer to the Applications Information section for further information on the design equations presented in Table 5.

#### Variable Definitions:

$V_{IN}$  = Input Voltage

$V_{OUT}$  = Output Voltage

DC = Power Switch Duty Cycle

$f_{OSC}$  = Switching Frequency

$I_{OUT}$  = Maximum Average Output Current

$I_{RIPPLE}$  = Inductor Ripple Current

$I_{RTYP}$  = 150mA for LT8570 and 75mA for LT8570-1

$k_{SC}$  = 0.6A for LT8570 and 0.3A for LT8570-1

$I_{RMIN}$  = 0.04A for LT8570 and 0.02A for LT8570-1

$I_{LIM}$  = 0.5A for LT8570 and 0.25A for LT8570-1

**Table 5. SEPIC Design Equations**

	PARAMETERS/EQUATIONS
<b>Step 1: Inputs</b>	Pick $V_{IN}$ , $V_{OUT}$ and $f_{OSC}$ to calculate equations below
<b>Step 2: DC</b>	$DC_{MAX} = \frac{V_{OUT} + 0.5V}{V_{IN(MIN)} + V_{OUT} + 0.5V - 0.4V}$ $DC_{MIN} = \frac{V_{OUT} + 0.5V}{V_{IN(MAX)} + V_{OUT} + 0.5V - 0.4V}$
<b>Step 3: L</b>	$L_{TYP} = \frac{(V_{IN(MIN)} - 0.4V) \cdot DC_{MAX}}{f_{OSC} \cdot I_{RTYP}} \quad (1)$ $L_{MIN} = \frac{(V_{IN(MIN)} - 0.4V) \cdot (2 \cdot DC_{MAX} - 1)}{k_{SC} \cdot (DC_{MAX} - 300ns \cdot f_{OSC}) \cdot f_{OSC} \cdot (1 - DC_{MAX})} \quad (2)$ $L_{MAX} = \frac{(V_{IN(MIN)} - 0.4V) \cdot DC_{MAX}}{f_{OSC} \cdot I_{RMIN}} \quad (3)$ <ul style="list-style-type: none"> <li>Solve equations 1, 2 and 3 for a range of L values</li> <li>The minimum of the L value range is the higher of <math>L_{TYP}</math> and <math>L_{MIN}</math></li> <li>The maximum of the L value range is <math>L_{MAX}</math></li> <li><math>L = L1 = L2</math> for coupled inductors</li> <li><math>L = L1 \parallel L2</math> for uncoupled inductors</li> </ul>
<b>Step 4: <math>I_{RIPPLE}</math></b>	$I_{RIPPLE(MIN)} = \frac{(V_{IN(MIN)} - 0.4V) \cdot DC_{MAX}}{f_{OSC} \cdot L}$ $I_{RIPPLE(MAX)} = \frac{(V_{IN(MAX)} - 0.4V) \cdot DC_{MIN}}{f_{OSC} \cdot L}$
<b>Step 5: <math>I_{OUT}</math></b>	$I_{OUT(MIN)} = \left( I_{LIM} - \frac{I_{RIPPLE(MIN)}}{2} \right) \cdot (1 - DC_{MAX})$ $I_{OUT(MAX)} = \left( I_{LIM} - \frac{I_{RIPPLE(MAX)}}{2} \right) \cdot (1 - DC_{MIN})$
<b>Step 6: D1</b>	$V_R > V_{IN} + V_{OUT}$ ; $I_{AVG} > I_{OUT}$
<b>Step 7: C1</b>	$V_{RATING} \geq V_{IN}$ $C1 \geq 0.47\mu F$ for LT8570, $C1 \geq 0.22\mu F$ for LT8570-1
<b>Step 8: <math>C_{OUT}</math></b>	$C_{OUT} \geq \frac{I_{OUT(MIN)} \cdot DC_{MAX}}{f_{OSC} \cdot 0.005 \cdot V_{OUT}}$
<b>Step 9: <math>C_{IN}</math></b>	$C_{IN} \geq C_{VIN} + C_{PWR} \geq \frac{I_{LIM} \cdot DC_{MAX}}{40 \cdot f_{OSC} \cdot 0.005 \cdot V_{IN(MIN)}} + \frac{I_{RIPPLE(MAX)}}{8 \cdot f_{OSC} \cdot 0.005 \cdot V_{IN(MAX)}}$ <ul style="list-style-type: none"> <li>Refer to the Capacitor Selection Section for definition of <math>C_{VIN}</math> and <math>C_{PWR}</math></li> </ul>
<b>Step 10: <math>R_{FBX}</math></b>	$R_{FBX} = \frac{V_{OUT} - 1.204V}{83.3\mu A}$
<b>Step 11: <math>R_T</math></b>	$R_T = \frac{85.5}{f_{OSC}} - 1$ ; $f_{OSC}$ in MHz and $R_T$ in k $\Omega$

**Note 1:** This table uses 0.5A and 0.25A for the peak switch current. Refer to the Electrical Characteristics Table and Typical Performance Characteristics plots for the peak switch current at an operating duty cycle.

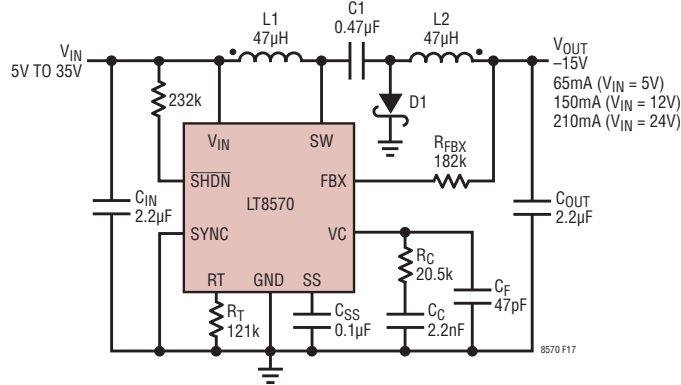
**Note 2:** The final values for  $C_{OUT}$ ,  $C_{IN}$  and C1 may deviate from the previous equations in order to obtain desired load transient performance.

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## APPLICATIONS INFORMATION

### DUAL INDUCTOR INVERTING CONVERTER COMPONENT SELECTION (COUPLED OR UNCOUPLED INDUCTORS)



**Figure 17. Dual Inductor Inverting Converter: The Component Values Given Are Typical Values for a 700kHz 5V-35V to -15V Inverting Topology Using Coupled Inductors**

Due to its unique FBX pin, the LT8570/LT8570-1 can work in an inverting configuration as in Figure 17. Changing the connections of L2 and the Schottky diode in the SEPIC topology results in negative output voltages. Output disconnect is inherently built into this topology due to the capacitor C1.

For a desired output voltage over a given input voltage range, Table 6 is a step-by-step set of equations to calculate component values for the LT8570/LT8570-1 when operating as a dual inductor inverting converter. Refer to the Applications Information section for further information on the design equations presented in Table 6.

#### Variable Definitions:

$V_{IN}$  = Input Voltage

$V_{OUT}$  = Output Voltage

DC = Power Switch Duty Cycle

$f_{OSC}$  = Switching Frequency

$I_{OUT}$  = Maximum Average Output Current

$I_{RIPPLE}$  = Inductor Ripple Current

$I_{RTYP}$  = 150mA for LT8570 and 75mA for LT8570-1

$k_{SC}$  = 0.6A for LT8570 and 0.3A for LT8570-1

$I_{RMIN}$  = 0.04A for LT8570 and 0.02A for LT8570-1

$I_{LIM}$  = 0.5A for LT8570 and 0.25A for LT8570-1

**Table 6. Dual Inductor Inverting Design Equations**

	PARAMETERS/EQUATIONS
<b>Step 1: Inputs</b>	Pick $V_{IN}$ , $V_{OUT}$ and $f_{OSC}$ to calculate equations below
<b>Step 2: DC</b>	$DC_{MAX} = \frac{ V_{OUT}  + 0.5V}{V_{IN(MIN)} +  V_{OUT}  + 0.5V - 0.4V}$ $DC_{MIN} = \frac{ V_{OUT}  + 0.5V}{V_{IN(MAX)} +  V_{OUT}  + 0.5V - 0.4V}$
<b>Step 3: L</b>	$L_{TYP} = \frac{(V_{IN(MIN)} - 0.4V) \cdot DC_{MAX}}{f_{OSC} \cdot I_{RTYP}} \quad (1)$ $L_{MIN} = \frac{(V_{IN(MIN)} - 0.4V) \cdot (2 \cdot DC_{MAX} - 1)}{k_{SC} \cdot (DC_{MAX} - 300ns \cdot f_{OSC}) \cdot f_{OSC} \cdot (1 - DC_{MAX})} \quad (2)$ $L_{MAX} = \frac{(V_{IN(MIN)} - 0.4V) \cdot DC_{MAX}}{f_{OSC} \cdot I_{RMIN}} \quad (3)$ <ul style="list-style-type: none"> <li>Solve equations 1, 2 and 3 for a range of L values</li> <li>The minimum of the L value range is the higher of <math>L_{TYP}</math> and <math>L_{MIN}</math></li> <li>The maximum of the L value range is <math>L_{MAX}</math></li> <li><math>L = L1 = L2</math> for coupled inductors</li> <li><math>L = L1    L2</math> for uncoupled inductors</li> </ul>
<b>Step 4: I<sub>RIPPLE</sub></b>	$I_{RIPPLE(MIN)} = \frac{(V_{IN(MIN)} - 0.4V) \cdot DC_{MAX}}{f_{OSC} \cdot L}$ $I_{RIPPLE(MAX)} = \frac{(V_{IN(MAX)} - 0.4V) \cdot DC_{MIN}}{f_{OSC} \cdot L}$
<b>Step 5: I<sub>OUT</sub></b>	$I_{OUT(MIN)} = \left( I_{LIM} - \frac{I_{RIPPLE(MIN)}}{2} \right) \cdot (1 - DC_{MAX})$ $I_{OUT(MAX)} = \left( I_{LIM} - \frac{I_{RIPPLE(MAX)}}{2} \right) \cdot (1 - DC_{MIN})$
<b>Step 6: D1</b>	$V_R > V_{IN} +  V_{OUT} $ ; $I_{AVG} > I_{OUT}$
<b>Step 7: C1</b>	$V_{RATING} \geq V_{IN(MAX)} +  V_{OUT} $ $C1 \geq 0.47\mu F$ for LT8570, $C1 \geq 0.22\mu F$ for LT8570-1
<b>Step 8: C<sub>OUT</sub></b>	$C_{OUT} \geq \frac{I_{RIPPLE(MAX)}}{8 \cdot f_{OSC} \cdot (0.005 \cdot  V_{OUT} )}$
<b>Step 9: C<sub>IN</sub></b>	$C_{IN} \geq C_{VIN} + C_{PWR} \geq \frac{I_{LIM} \cdot DC_{MAX}}{40 \cdot f_{OSC} \cdot 0.005 \cdot V_{IN(MIN)}} + \frac{I_{RIPPLE(MAX)}}{8 \cdot f_{OSC} \cdot 0.005 \cdot V_{IN(MAX)}}$ <ul style="list-style-type: none"> <li>Refer to the Capacitor Selection Section for definition of <math>C_{VIN}</math> and <math>C_{PWR}</math></li> </ul>
<b>Step 10: R<sub>FBX</sub></b>	$R_{FBX} = \frac{ V_{OUT}  + 3mV}{83.3\mu A}$
<b>Step 11: R<sub>T</sub></b>	$R_T = \frac{85.5}{f_{OSC}} - 1$ ; $f_{OSC}$ in MHz and $R_T$ in k $\Omega$

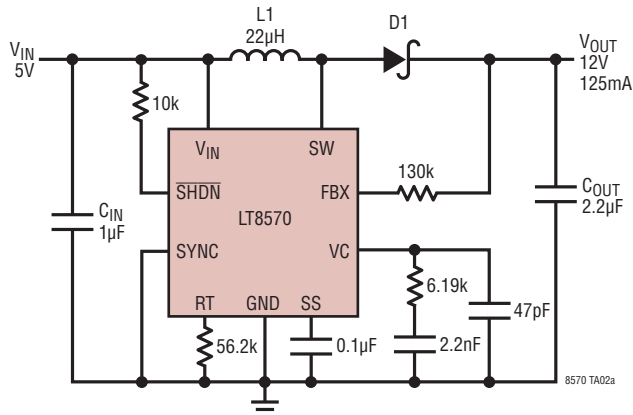
**Note 1:** This table uses 0.5A and 0.25A for the peak switch current. Refer to the Electrical Characteristics Table and Typical Performance Characteristics plots for the peak switch current at an operating duty cycle.

**Note 2:** The final values for  $C_{OUT}$ ,  $C_{IN}$  and  $C1$  may deviate from the previous equations in order to obtain desired load transient performance.

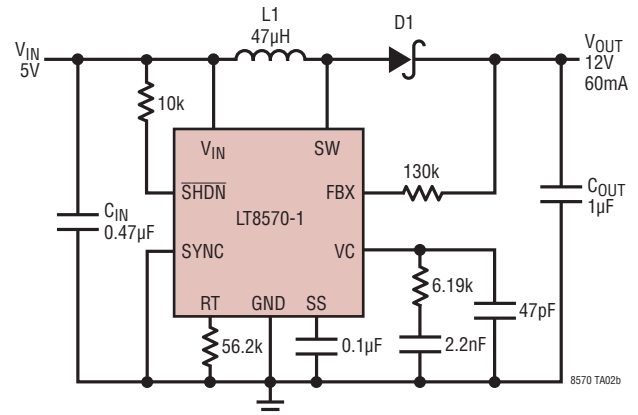


# TYPICAL APPLICATIONS

## 1.5MHz, 5V to 12V Output Boost Converter

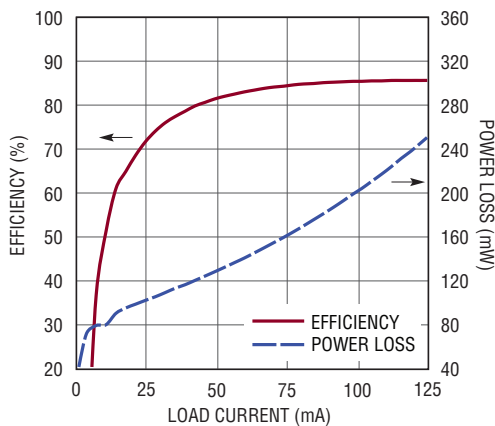


L1: WÜRTH 22μH WE-LQS 74404042220  
D1: DIODES INC. PD3S140  
C<sub>IN</sub>: 1μF, 16V, 0805, X7R  
C<sub>OUT</sub>: 2.2μF, 16V, 0805, X7R



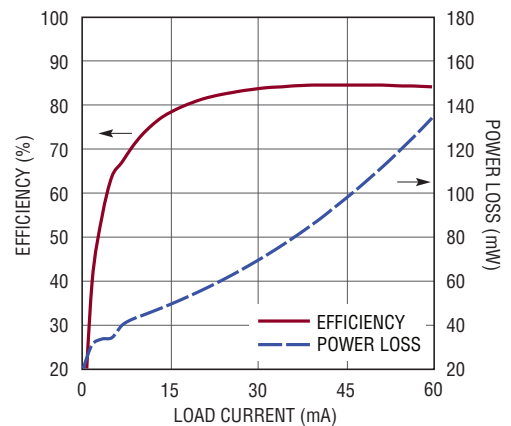
L1: WÜRTH 47μH WE-LQS 74404032470  
D1: DIODES INC. PD3S140  
C<sub>IN</sub>: 0.47μF, 16V, 0805, X7R  
C<sub>OUT</sub>: 1μF, 16V, 0805, X7R

### Efficiency and Power Loss (LT8570)



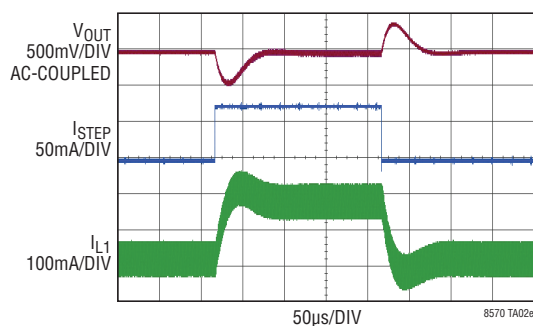
8570 TA02c

### Efficiency and Power Loss (LT8570-1)



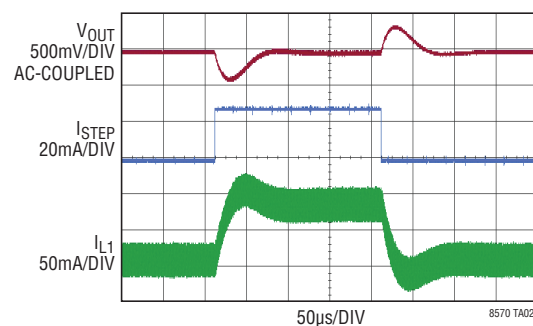
8570 TA02d

### 30mA to 90mA to 30mA Output Load Step (LT8570)



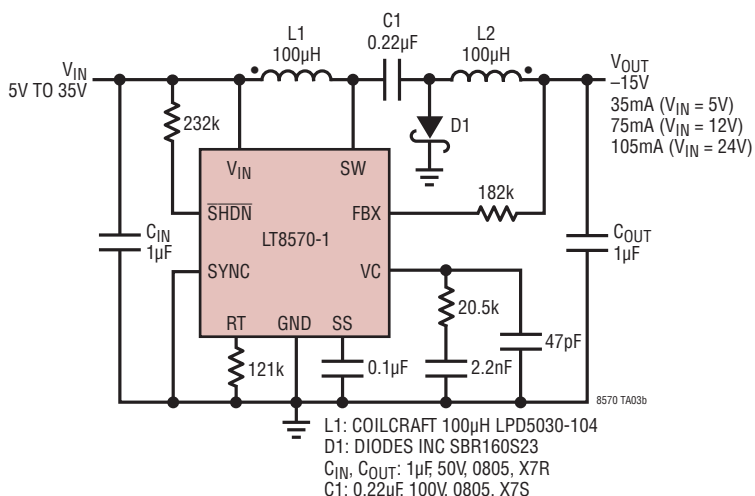
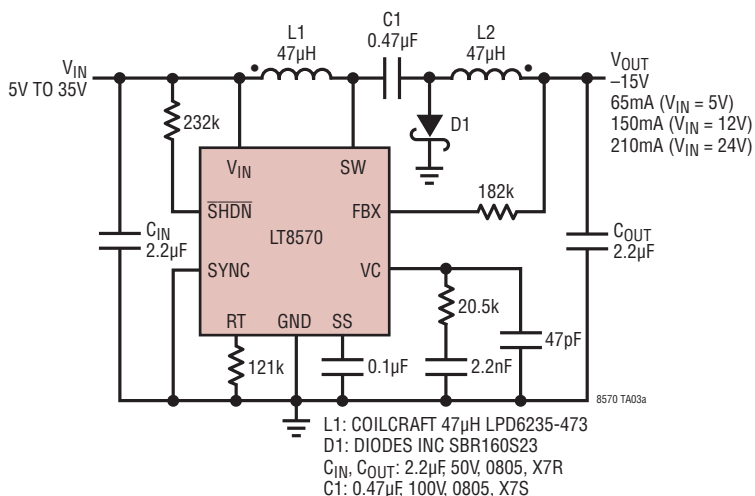
8570 TA02e

### 15mA to 45mA to 15mA Output Load Step (LT8570-1)

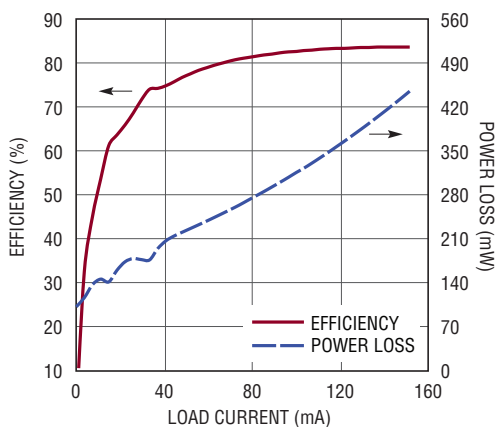


8570 TA02f

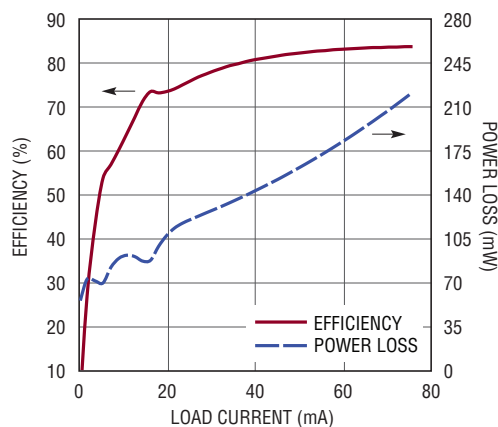
## 700kHz, -15V Output Inverting Converter Accepts 5V to 35V Input



### Efficiency and Power Loss (LT8570, $V_{IN} = 12V$ )

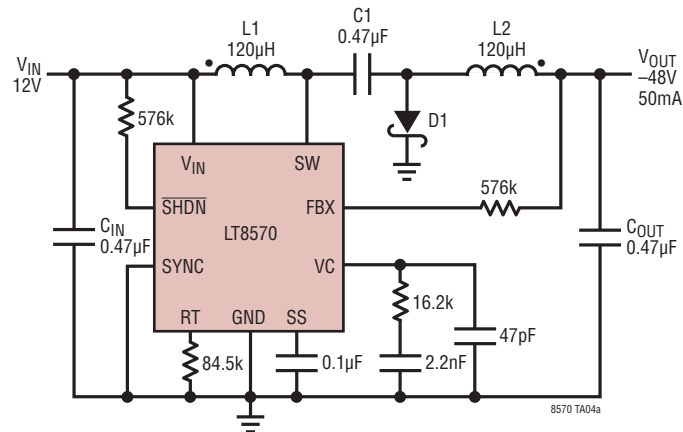


### Efficiency and Power Loss (LT8570-1, $V_{IN} = 12V$ )



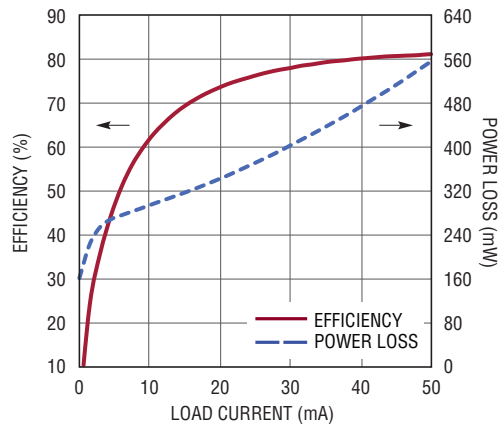
# TYPICAL APPLICATIONS

## 1MHz Inverting Converter Generates -48V Output From 12V Input



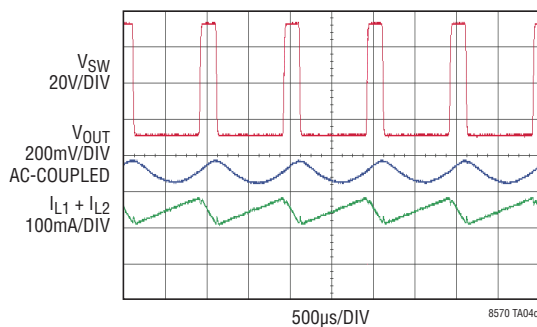
L1, L2: COILCRAFT 120µH MSD7342-124  
D1: DIODES, INC. DFSL1100  
C<sub>IN</sub>, C<sub>OUT</sub>: 0.47µF, 50V, 0805, X7R  
C1: 0.47µF, 100V, 0805, X7S

## Efficiency and Power Loss



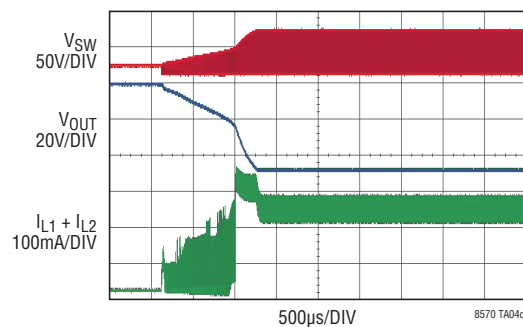
8570 TA04b

## Switching Waveforms



8570 TA04c

## Start-Up Waveforms

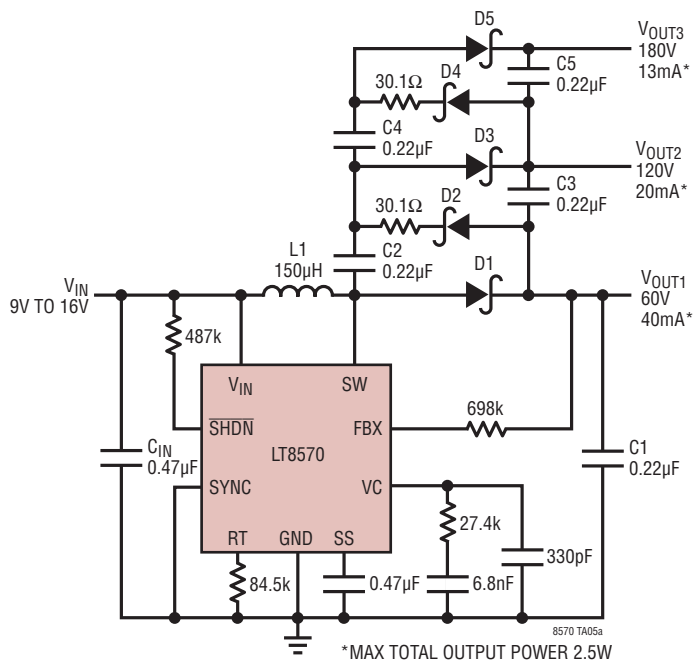


8570 TA04d

## TYPICAL APPLICATIONS

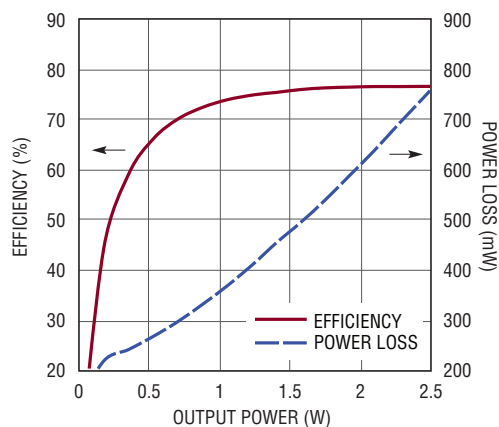
### VFD (Vacuum Fluorescent Display) Power Supply Switches at 1MHz

**Danger High Voltage! Operation by High Voltage Trained Personnel Only**

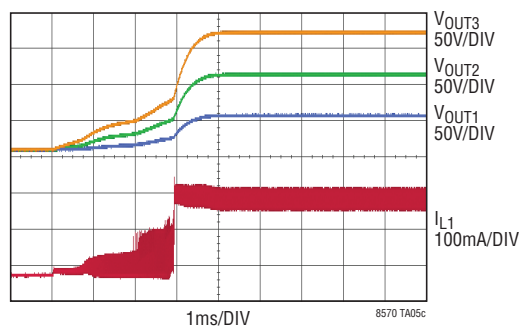


L1: WÜRTH 150µH WE-PD2SR 744787151  
D1-D5: CENTRAL SEMI CMOD6263  
C1N: 0.47µF, 25V, 0805, X7R  
C1-C5: 0.22µF, 100V, 0805, X7S

**Efficiency and Power Loss**  
(V<sub>IN</sub> = 12V with Load on V<sub>OUT3</sub>)

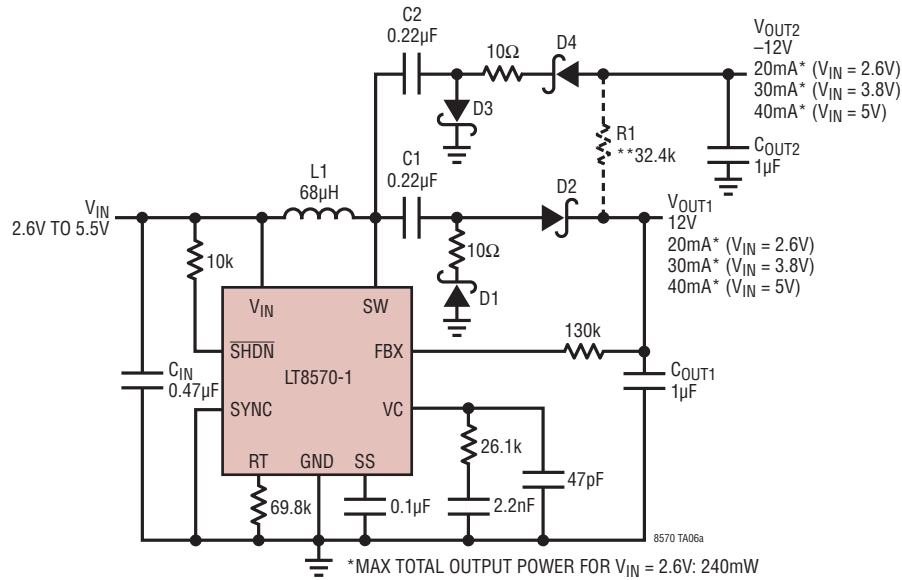


**Start-Up Waveforms**



# TYPICAL APPLICATIONS

## 1.2MHz Charge Pump Creates $\pm 12V$ From a Single Lithium Ion Battery

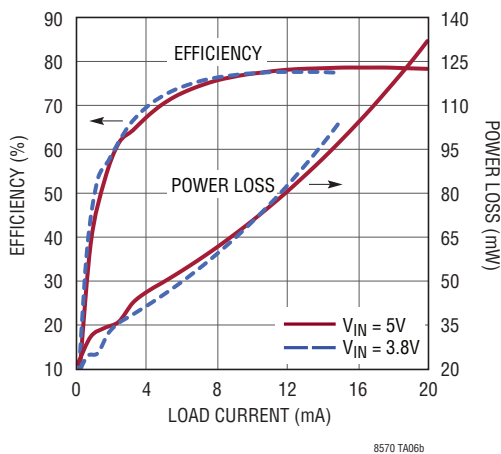


L1: WÜRTH 68μH WE-LQS 74404054680  
D1-D4: DIODES INC SDM10K45  
C\_IN: 0.47μF, 25V, 0805, X7R  
C\_OUT1, C\_OUT2: 1μF, 16V, 0805, X7R  
C1-C2: 0.22μF, 25V, 0805, X7R

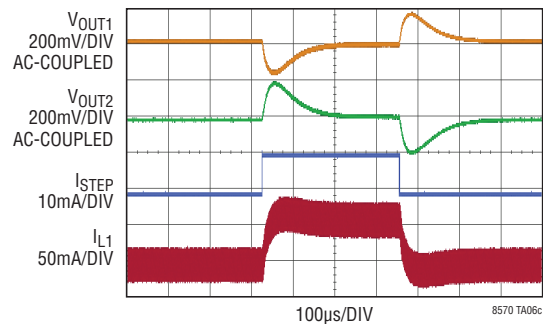
\*MAX TOTAL OUTPUT POWER FOR  $V_{IN} = 2.6V$ : 240mW  
 $V_{IN} = 3.8V$ : 350mW  
 $V_{IN} = 5V$ : 480mW

\*\*IF DRIVING ASYMMETRICAL LOADS, PLACE A 32.4k RESISTOR FROM THE 12V OUTPUT TO THE -12V OUTPUT FOR IMPROVED LOAD REGULATION OF THE -12V OUTPUT

Efficiency and Power Loss  
(Load Between  $V_{OUT1}$  AND  $V_{OUT2}$ )

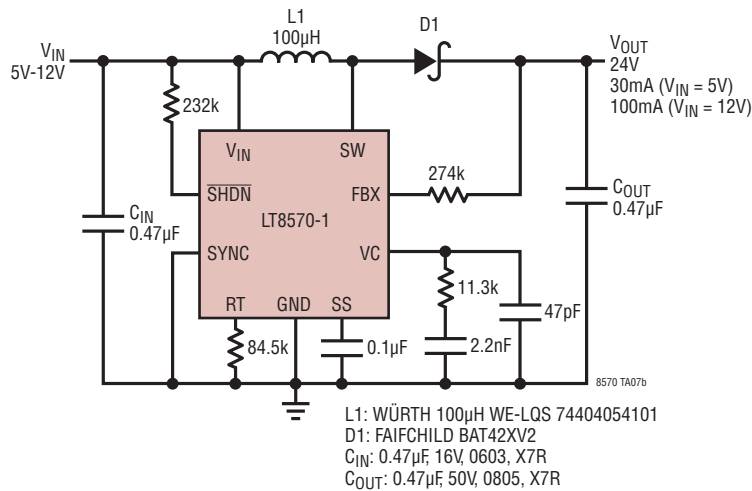
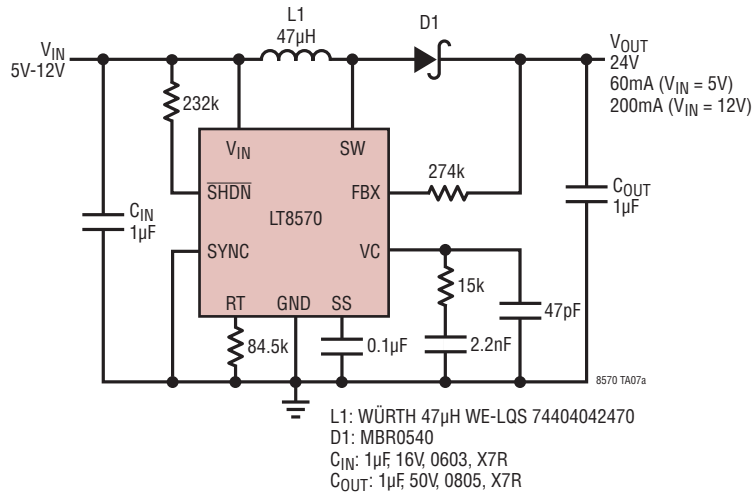


Transient Response with 5mA to 15mA to 5mA Output Load Step ( $V_{IN} = 5V$ )

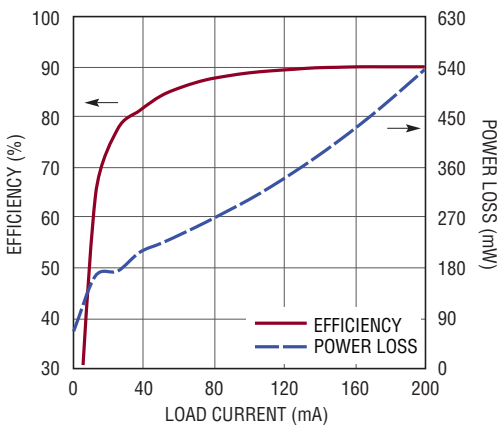


## TYPICAL APPLICATIONS

### 1MHz Boost Converter Generates 24V from 5V-12V Input

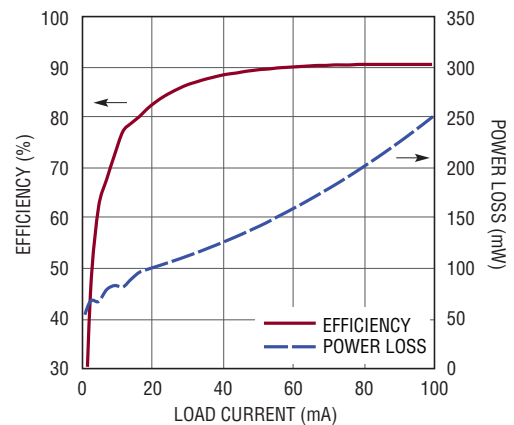


Efficiency and Power Loss  
(LT8570, V<sub>IN</sub> = 12V)



8570 TA07c

Efficiency and Power Loss  
(LT8570-1, V<sub>IN</sub> = 12V)

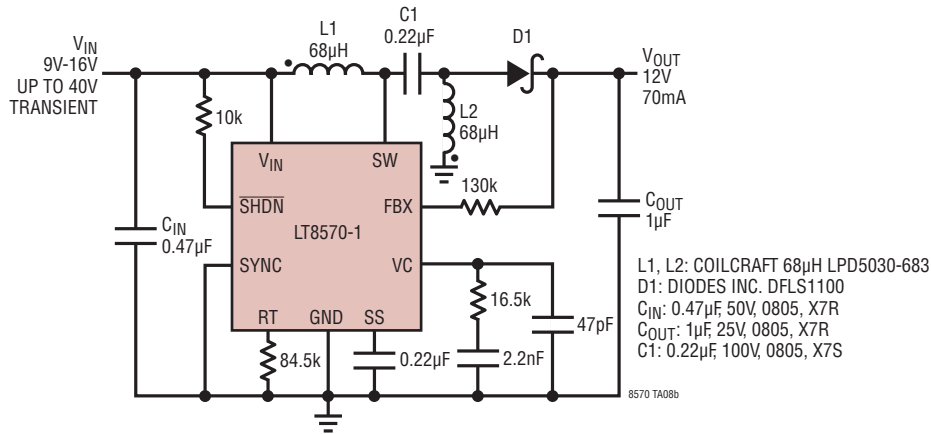
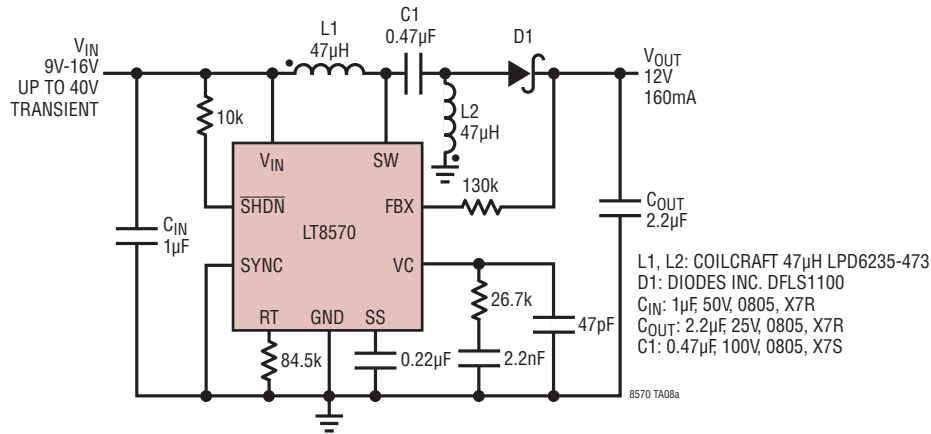


8570 TA07d

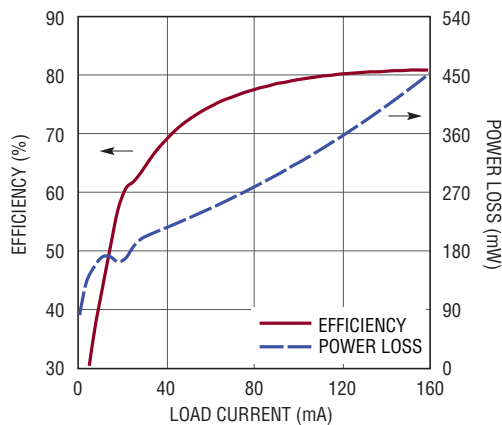
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# TYPICAL APPLICATIONS

## 12V Battery Stabilizer Survives 40V Transients

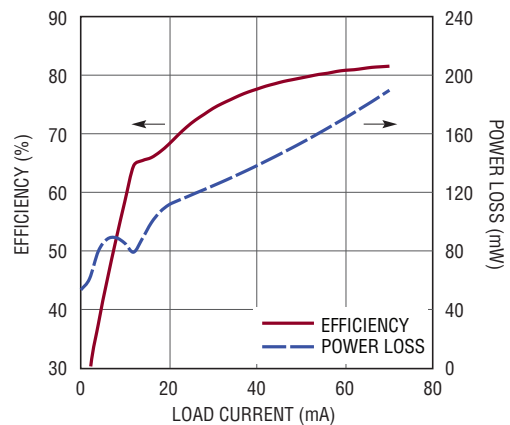


Efficiency and Power Loss  
(LT8570,  $V_{IN} = 12V$ )



8570 TA08c

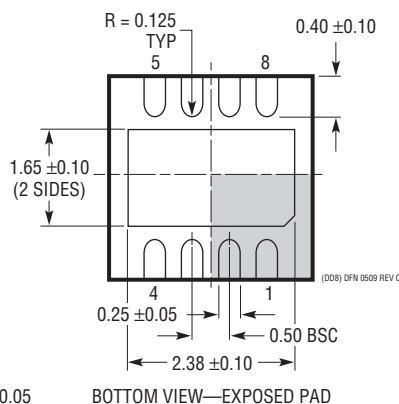
Efficiency and Power Loss  
(LT8570-1,  $V_{IN} = 12V$ )



8570 TA08d

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**DD Package**  
**8-Lead Plastic DFN (3mm × 3mm)**  
 (Reference LTC DWG # 05-08-1698 Rev C)



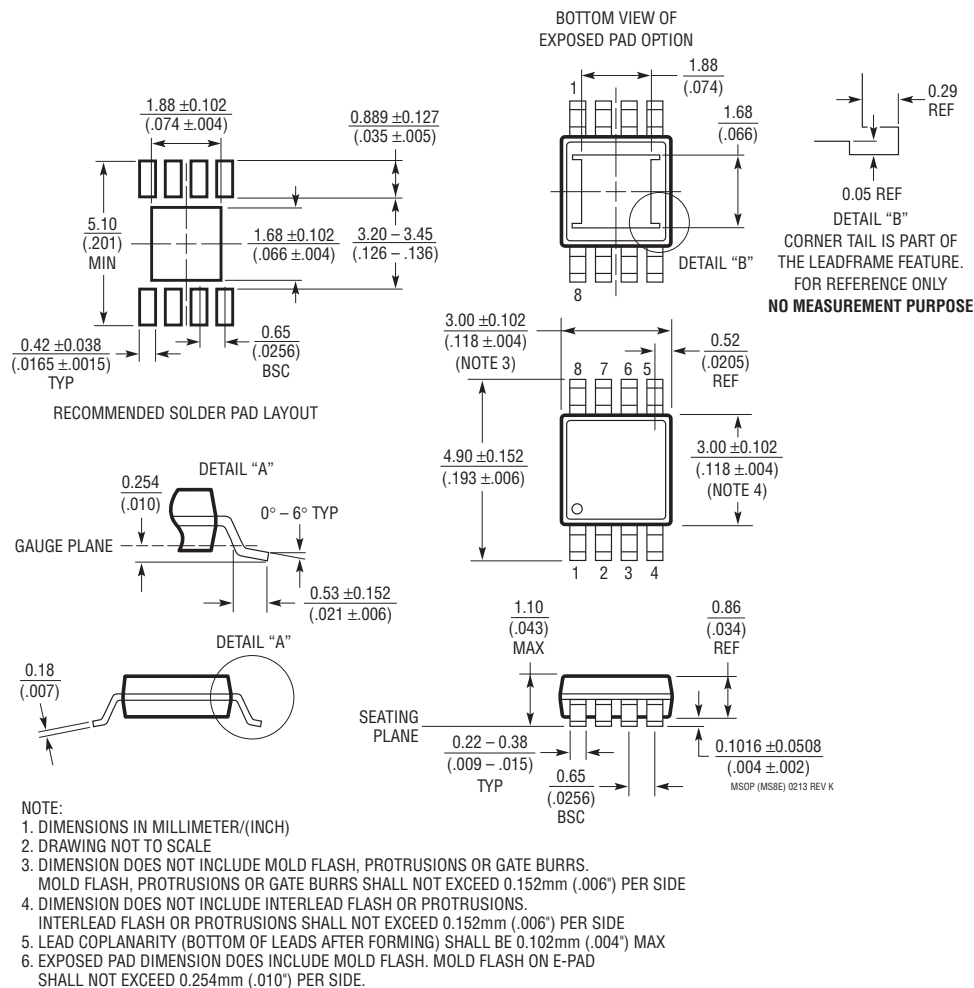
1. DRAWING TO BE MADE A JEDEC PACKAGE OUTLINE M0-229 VARIATION OF (WEED-1)
2. DRAWING NOT TO SCALE
3. ALL DIMENSIONS ARE IN MILLIMETERS
4. DIMENSIONS OF EXPOSED PAD ON BOTTOM OF PACKAGE DO NOT INCLUDE MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.15mm ON ANY SIDE
5. EXPOSED PAD SHALL BE SOLDER PLATED
6. SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION ON TOP AND BOTTOM OF PACKAGE



## PACKAGE DESCRIPTION

Please refer to <http://www.linear.com/product/LT8570#packaging> for the most recent package drawings.

### MS8E Package 8-Lead Plastic MSOP, Exposed Die Pad (Reference LTC DWG # 05-08-1662 Rev K)



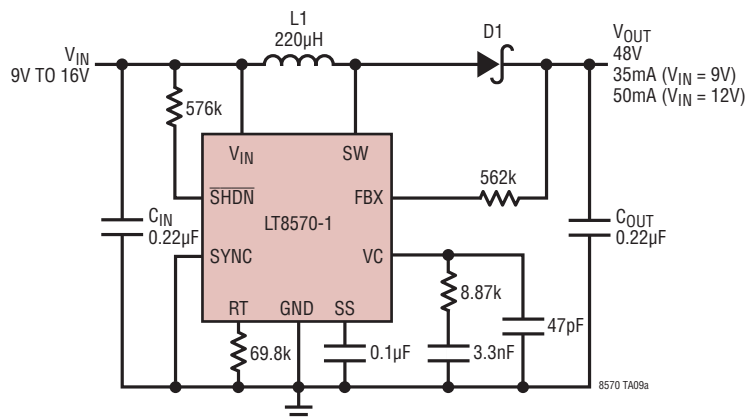
## REVISION HISTORY

REV	DATE	DESCRIPTION	PAGE NUMBER
A	09/16	Added H-grade	2
		Clarified specification to include -40°C to 150°C H-grade limits	2
		Clarified Note 2 to include H-grade	3
		Clarified inductor paragraph on Applications Information	12

# LT8570/LT8570-1

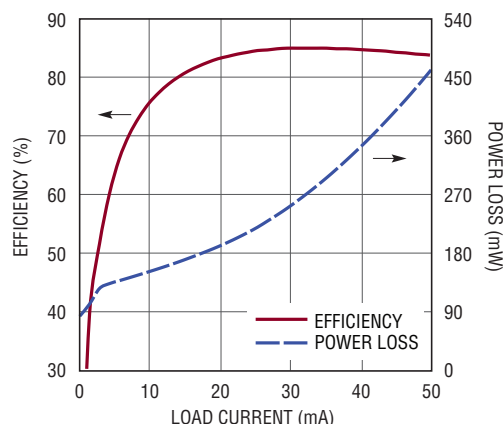
## TYPICAL APPLICATION

### 1.2MHz Boost Converter Creates 48V from 9V-16V Input



L1: COILCRAFT 220µH LPS6235-224  
D1: DIODES INC. ZHCS506  
CIN: 0.22µF 25V, 0603, X7R  
COUT: 0.22µF 50V, 0805, X7R

### Efficiency and Power Loss (VIN = 12V)



## RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LT1613	550mA (ISW), 1.4MHz High Efficiency Step-Up DC/DC Converter	VIN: 0.9V to 10V, VOUT(MAX) = 34V, IQ = 3mA, ISD < 1µA, ThinSOT Package
LT1618	1.5A (ISW), 1.4MHz High Efficiency Step-Up DC/DC Converter	VIN: 1.6V to 18V, VOUT(MAX) = 35V, IQ = 1.8mA, ISD < 1µA, MS10, 3mm × 3mm DFN Packages
LT1930/LT1930A	1A (ISW), 1.2MHz/2.2MHz High Efficiency Step-Up DC/DC Converter	VIN: 2.6V to 16V, VOUT(MAX) = 34V, IQ = 4.2mA/5.5mA, ISD < 1µA, ThinSOT Package
LT1935	2A (ISW), 40V, 1.2MHz High Efficiency Step-Up DC/DC Converter	VIN: 2.3V to 16V, VOUT(MAX) = 38V, IQ = 3mA, ISD < 1µA, ThinSOT Package
LT1944/LT1944-1	Dual Output 350mA (ISW), Constant Off-Time, High Efficiency Step-Up DC/DC Converter	VIN: 1.2V to 15V, VOUT(MAX) = 34V, IQ = 20µA, ISD < 1µA, MS10 Package
LT1946/LT1946A	1.5A (ISW), 1.2MHz/2.7MHz High Efficiency Step-Up DC/DC Converter	VIN: 2.6V to 16V, VOUT(MAX) = 34V, IQ = 3.2mA, ISD < 1µA, MS8E Package
LT3467	1.1A (ISW), 1.3MHz High Efficiency Step-Up DC/DC Converter	VIN: 2.4V to 16V, VOUT(MAX) = 40V, IQ = 1.2mA, ISD < 1µA, ThinSOT, 2mm × 3mm DFN Packages
LT3479	3A Full-Featured DC/DC Converter with Soft-Start and Inrush Current Protection	VIN: 2.5V to 24V, VOUT(MAX) = 40V, IQ = 5mA, ISD < 1µA, DFN, TSSOP Packages
LT3580	2A (ISW), 42V, 2.5MHz, High Efficiency Step-Up DC/DC Converter	VIN: 2.5V to 32V, VOUT(MAX) = 42V, IQ = 1mA, ISD < 1µA, 3mm × 3mm DFN-8, MSOP-8E
LT3581	3.3A (ISW), 42V, 2.5MHz, High Efficiency Step-Up DC/DC Converter	VIN: 2.5V to 22V, VOUT(MAX) = 42V, IQ = 1.9mA, ISD < 1µA, 4mm × 3mm DFN-14, MSOP-16E
LT3579	6A (ISW), 42V, 2.5MHz, High Efficiency, Step-Up DC/DC Converter	VIN: 2.5V to 16V, VOUT(MAX) = 42V, IQ = 1.9mA, ISD < 1µA, 4mm × 5mm DFN-20, TSSOP-20
LT8582	Dual Channel, 3A (ISW), 42V, 2.5MHz, High Efficiency Step-Up DC/DC Converter	VIN: 2.5V to 22V, VOUT(MAX) = 42V, IQ = 2.1mA, ISD < 1µA, 4mm × 7mm DFN-24
LT8580	1A (ISW), 65V 1.5MHz, High Efficiency Step-Up DC/DC Converter	VIN: 2.55V to 40V, VOUT(MAX) = 65V, IQ = 1.2mA, ISD < 1µA, 3mm × 3mm DFN-8, MSOP-8E

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